

## LM4562 Dual High-Performance, High-Fidelity Audio Operational Amplifier

Check for Samples: [LM4562](#)

### FEATURES

- Easily Drives 600Ω Loads
- Optimized for Superior Audio Signal Fidelity
- Output Short Circuit Protection
- PSRR and CMRR Exceed 120dB (Typ)
- SOIC, PDIP, and TO-99 Packages

### APPLICATIONS

- Ultra High-Quality Audio Amplification
- High-Fidelity Preamplifiers
- High-Performance Professional Audio
- High-Fidelity Active Equalization and Crossover Networks
- High-Performance Line Drivers and Receivers

### KEY SPECIFICATIONS

- Power Supply Voltage Range:  $\pm 2.5\text{V}$  to  $\pm 17\text{V}$
- THD+N ( $A_V = 1$ ,  $V_{OUT} = 3V_{RMS}$ ,  $f_{IN} = 1\text{kHz}$ )
  - $R_L = 2\text{k}\Omega$ : 0.00003% (typ)
  - $R_L = 600\Omega$ : 0.00003% (typ)
- Input Noise Density:  $2.7\text{nV}/\sqrt{\text{Hz}}$  (typ)
- Slew Rate:  $\pm 20\text{V}/\mu\text{s}$  (typ)
- Gain Bandwidth Product: 55MHz (typ)
- Open Loop Gain ( $R_L = 600\Omega$ ): 140dB (typ)
- Input Bias Current: 10nA (typ)
- Input Offset Voltage: 0.1mV (typ)
- DC Gain Linearity Error: 0.000009%

### DESCRIPTION

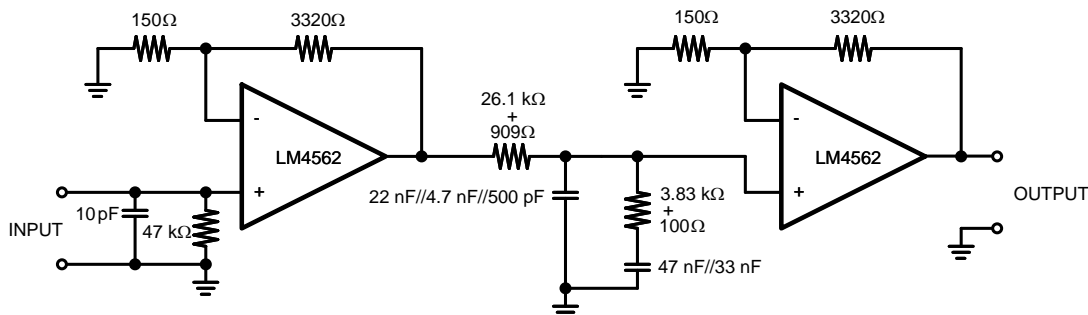
The LM4562 is part of the ultra-low distortion, low-noise, high-slew-rate operational amplifier series optimized and fully specified for high-performance, high-fidelity applications. The LM4562 audio operational amplifiers deliver superior audio signal amplification for outstanding audio performance. The LM4562 combines extremely low voltage noise density ( $2.7\text{nV}/\sqrt{\text{Hz}}$ ) with vanishingly low THD+N (0.00003%) to easily satisfy the most demanding audio applications. To ensure that the most challenging loads are driven without compromise, the LM4562 has a high slew rate of  $\pm 20\text{V}/\mu\text{s}$  and an output current capability of  $\pm 26\text{mA}$ . Further, dynamic range is maximized by an output stage that drives  $2\text{k}\Omega$  loads to within 1V of either power supply voltage and to within 1.4V when driving  $600\Omega$  loads.

The LM4562's outstanding CMRR (120dB), PSRR (120dB), and  $V_{OS}$  (0.1mV) give the amplifier excellent operational amplifier DC performance.

The LM4562 has a wide supply range of  $\pm 2.5\text{V}$  to  $\pm 17\text{V}$ . Over this supply range the LM4562's input circuitry maintains excellent common-mode and power supply rejection, as well as maintaining its low input bias current. The LM4562 is unity gain stable. This Audio Operational Amplifier achieves outstanding AC performance while driving complex loads with values as high as 100pF.

The LM4562 is available in an 8-lead narrow body SOIC, an 8-lead PDIP, and an 8-lead TO-99.

### TYPICAL APPLICATION



A. 1% metal film resistors, 5% polypropylene capacitors

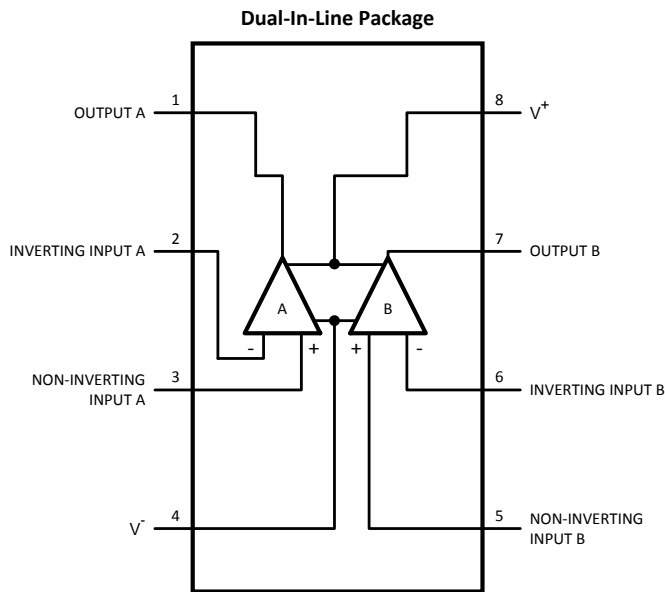
### Passively Equalized RIAA Phono Preamplifier



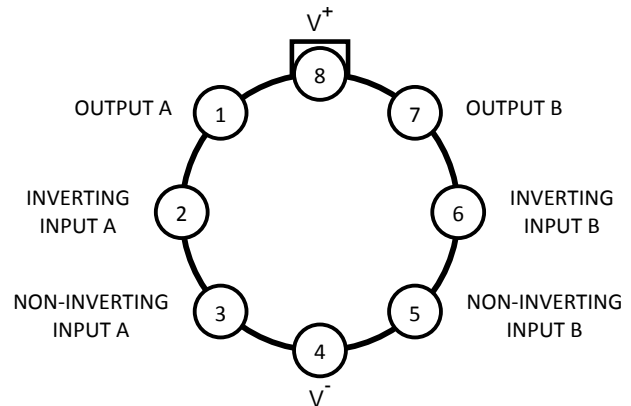
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

All trademarks are the property of their respective owners.

## CONNECTION DIAGRAMS



**Figure 1. 8-Lead SOIC (D Package)  
8-Lead PDIP (P Package)**



**Figure 2. 8-Lead TO-99 (LMC Package)**



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### ABSOLUTE MAXIMUM RATINGS<sup>(1)(2)(3)</sup>

Power Supply Voltage ( $V_S = V^+ - V^-$ )		36V
Storage Temperature		-65°C to 150°C
Input Voltage		(V-) - 0.7V to (V+) + 0.7V
Output Short Circuit <sup>(4)</sup>		Continuous
Power Dissipation		Internally Limited
ESD Susceptibility <sup>(5)</sup>		2000V
ESD Susceptibility <sup>(6)</sup>	Pins 1, 4, 7 and 8	200V
	Pins 2, 3, 5 and 6	100V
Junction Temperature		150°C
Thermal Resistance	$\theta_{JA}$ (D)	145°C/W
	$\theta_{JA}$ (P)	102°C/W
	$\theta_{JA}$ (LMC)	150°C/W
	$\theta_{JC}$ (LMC)	35°C/W
Temperature Range ( $T_{MIN} \leq T_A \leq T_{MAX}$ )		-40°C $\leq$ $T_A$ $\leq$ 85°C
Supply Voltage Range		$\pm 2.5V \leq V_S \leq \pm 17V$

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur.
- (2) Operating Ratings indicate conditions for which the device is functional, but do not ensure specific performance limits. For ensured specifications and test conditions, see the Electrical Characteristics. The ensured specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.
- (3) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/Distributors for availability and specifications.
- (4) Amplifier output connected to GND, any number of amplifiers within a package.
- (5) Human body model, 100pF discharged through a 1.5k $\Omega$  resistor.
- (6) Machine Model ESD test is covered by specification EIAJ IC-121-1981. A 200pF cap is charged to the specified voltage and then discharged directly into the IC with no external series resistor (resistance of discharge path must be under 50 $\Omega$ ).

**ELECTRICAL CHARACTERISTICS FOR THE LM4562<sup>(1)(2)</sup>**

 The specifications apply for  $V_S = \pm 15V$ ,  $R_L = 2k\Omega$ ,  $f_{IN} = 1kHz$ ,  $T_A = 25^\circ C$ , unless otherwise specified.

Symbol	Parameter	Conditions	LM4562		Units (Limits)
			Typical <sup>(3)</sup>	Limit <sup>(4)</sup>	
THD+N	Total Harmonic Distortion + Noise	$A_V = 1$ , $V_{OUT} = 3V_{rms}$ $R_L = 2k\Omega$ $R_L = 600\Omega$	0.00003 0.00003	0.00009	% (max)
IMD	Intermodulation Distortion	$A_V = 1$ , $V_{OUT} = 3V_{RMS}$ Two-tone, 60Hz & 7kHz 4:1	0.00005		%
GBWP	Gain Bandwidth Product		55	45	MHz (min)
SR	Slew Rate		$\pm 20$	$\pm 15$	V/ $\mu s$ (min)
FPBW	Full Power Bandwidth	$V_{OUT} = 1V_{P-P}$ , $-3dB$ referenced to output magnitude at $f = 1kHz$	10		MHz
$t_s$	Settling time	$A_V = -1$ , 10V step, $C_L = 100pF$ 0.1% error range	1.2		$\mu s$
$e_n$	Equivalent Input Noise Voltage	$f_{BW} = 20Hz$ to $20kHz$	0.34	0.65	$\mu V_{RMS}$ (max)
	Equivalent Input Noise Density	$f = 1kHz$ $f = 10Hz$	2.7 6.4	4.7	$nV/\sqrt{Hz}$ (max)
$i_n$	Current Noise Density	$f = 1kHz$ $f = 10Hz$	1.6 3.1		$pA/\sqrt{Hz}$
$V_{OS}$	Offset Voltage		$\pm 0.1$	$\pm 0.7$	mV (max)
$\Delta V_{OS}/\Delta Temp$	Average Input Offset Voltage Drift vs Temperature	$-40^\circ C \leq T_A \leq 85^\circ C$	0.2		$\mu V/^\circ C$
PSRR	Average Input Offset Voltage Shift vs Power Supply Voltage	$\Delta V_S = 20V^{(5)}$	120	110	dB (min)
ISO <sub>CH-CH</sub>	Channel-to-Channel Isolation	$f_{IN} = 1kHz$ $f_{IN} = 20kHz$	118 112		dB
$I_B$	Input Bias Current	$V_{CM} = 0V$	10	72	nA (max)
$\Delta I_{OS}/\Delta Temp$	Input Bias Current Drift vs Temperature	$-40^\circ C \leq T_A \leq 85^\circ C$	0.1		nA/ $^\circ C$
$I_{OS}$	Input Offset Current	$V_{CM} = 0V$	11	65	nA (max)
$V_{IN-CM}$	Common-Mode Input Voltage Range		+14.1 -13.9	(V+) - 2.0 (V-) + 2.0	V (min)
CMRR	Common-Mode Rejection	$-10V < V_{cm} < 10V$	120	110	dB (min)
$Z_{IN}$	Differential Input Impedance		30		k $\Omega$
	Common Mode Input Impedance	$-10V < V_{cm} < 10V$	1000		M $\Omega$
$A_{VOL}$	Open Loop Voltage Gain	$-10V < V_{out} < 10V$ , $R_L = 600\Omega$	140	125	dB (min)
		$-10V < V_{out} < 10V$ , $R_L = 2k\Omega$	140		
		$-10V < V_{out} < 10V$ , $R_L = 10k\Omega$	140		
$V_{OUTMAX}$	Maximum Output Voltage Swing	$R_L = 600\Omega$	$\pm 13.6$	$\pm 12.5$	V (min)
		$R_L = 2k\Omega$	$\pm 14.0$		
		$R_L = 10k\Omega$	$\pm 14.1$		
$I_{OUT}$	Output Current	$R_L = 600\Omega$ , $V_S = \pm 17V$	$\pm 26$	$\pm 23$	mA (min)
$I_{OUT-CC}$	Instantaneous Short Circuit Current		+53 -42		mA
$R_{OUT}$	Output Impedance	$f_{IN} = 10kHz$ Closed-Loop	0.01		$\Omega$
		Open-Loop	13		

(1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur.

(2) Operating Ratings indicate conditions for which the device is functional, but do not ensure specific performance limits. For ensured specifications and test conditions, see the Electrical Characteristics. The ensured specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

(3) Typical specifications are specified at  $+25^\circ C$  and represent the most likely parametric norm.

(4) Tested limits are specified to AOQL (Average Outgoing Quality Level).

(5) PSRR is measured as follows:  $V_{OS}$  is measured at two supply voltages,  $\pm 5V$  and  $\pm 15V$ .  $PSRR = |20\log(\Delta V_{OS}/\Delta V_S)|$ .

**ELECTRICAL CHARACTERISTICS FOR THE LM4562<sup>(1)(2)</sup> (continued)**

The specifications apply for  $V_S = \pm 15V$ ,  $R_L = 2k\Omega$ ,  $f_{IN} = 1kHz$ ,  $T_A = 25^\circ C$ , unless otherwise specified.

Symbol	Parameter	Conditions	LM4562		Units (Limits)
			Typical <sup>(3)</sup>	Limit <sup>(4)</sup>	
$C_{LOAD}$	Capacitive Load Drive Overshoot	100pF	16		%
$I_S$	Total Quiescent Current	$I_{OUT} = 0mA$	10	12	mA (max)

TYPICAL PERFORMANCE CHARACTERISTICS

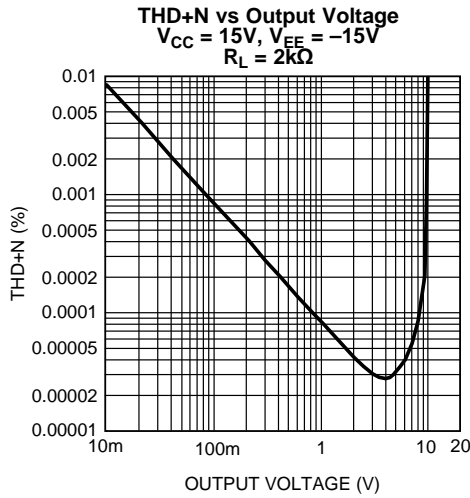


Figure 3.

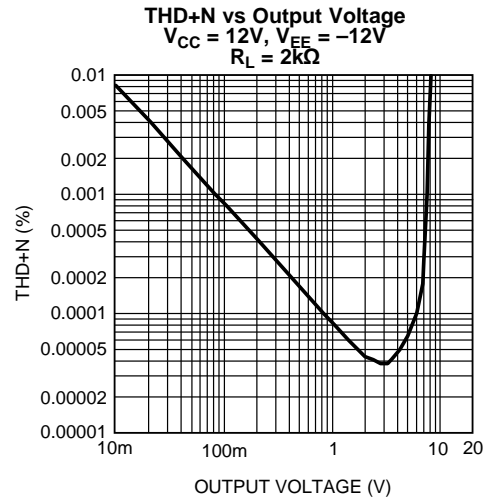


Figure 4.

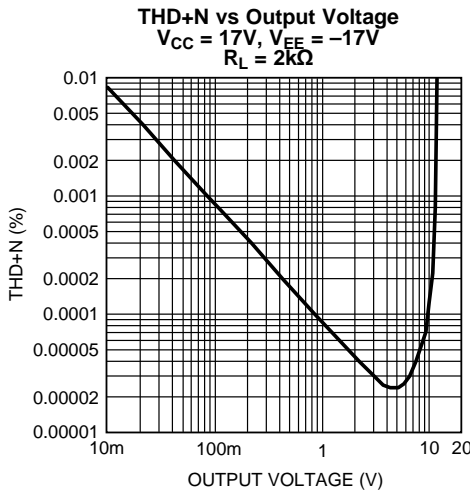


Figure 5.

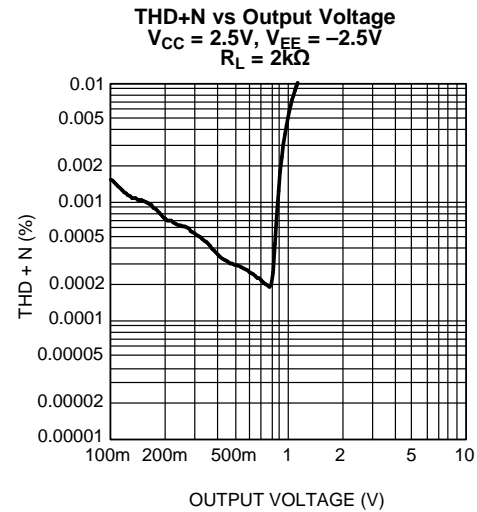


Figure 6.

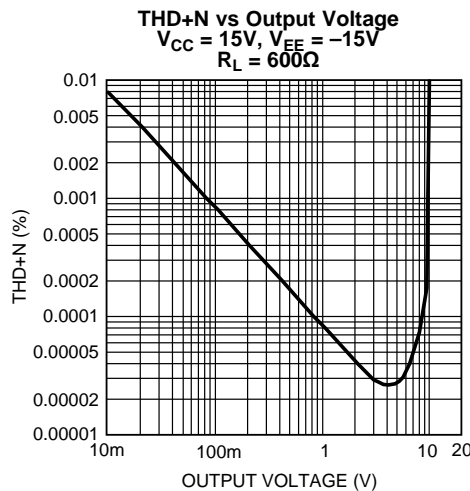


Figure 7.

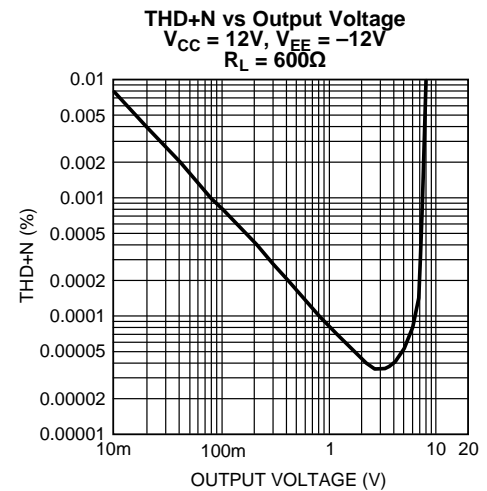
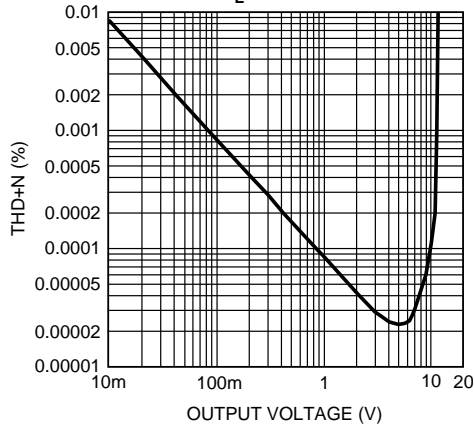


Figure 8.

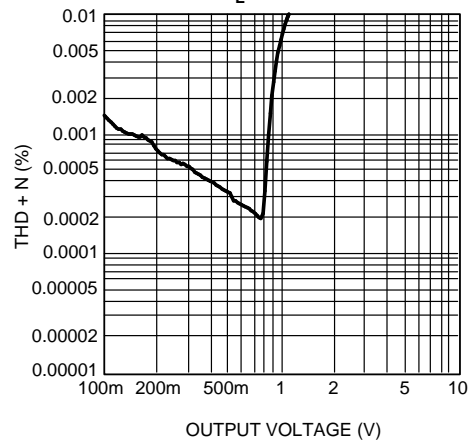
**TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

**THD+N vs Output Voltage**  
 $V_{CC} = 17V, V_{EE} = -17V$   
 $R_L = 600\Omega$



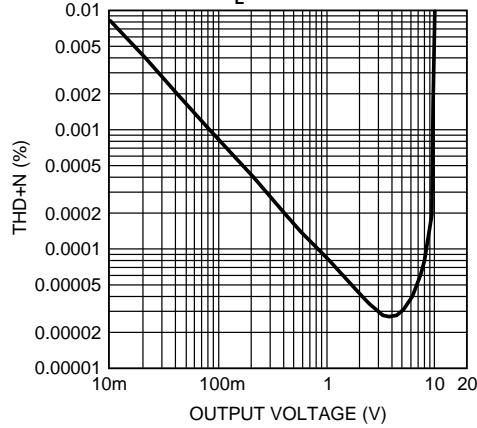
**Figure 9.**

**THD+N vs Output Voltage**  
 $V_{CC} = 2.5V, V_{EE} = -2.5V$   
 $R_L = 600\Omega$



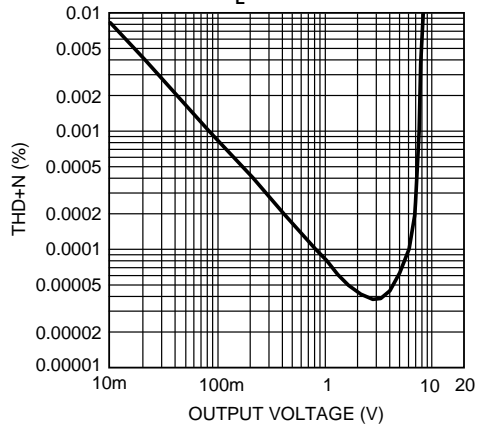
**Figure 10.**

**THD+N vs Output Voltage**  
 $V_{CC} = 15V, V_{EE} = -15V$   
 $R_L = 10k\Omega$



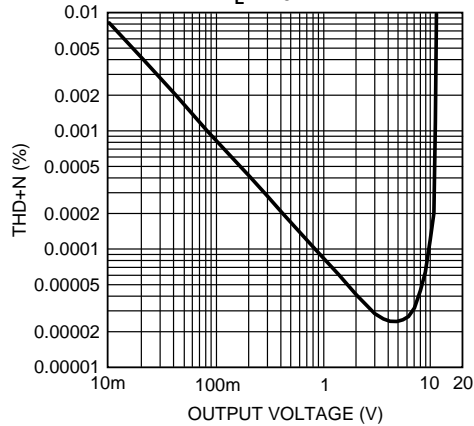
**Figure 11.**

**THD+N vs Output Voltage**  
 $V_{CC} = 12V, V_{EE} = -12V$   
 $R_L = 10k\Omega$



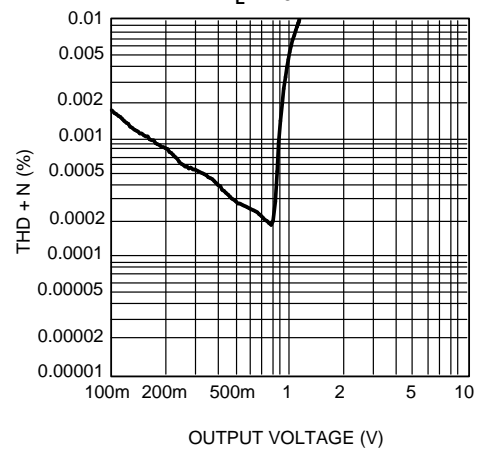
**Figure 12.**

**THD+N vs Output Voltage**  
 $V_{CC} = 17V, V_{EE} = -17V$   
 $R_L = 10k\Omega$



**Figure 13.**

**THD+N vs Output Voltage**  
 $V_{CC} = 2.5V, V_{EE} = -2.5V$   
 $R_L = 10k\Omega$



**Figure 14.**

**TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

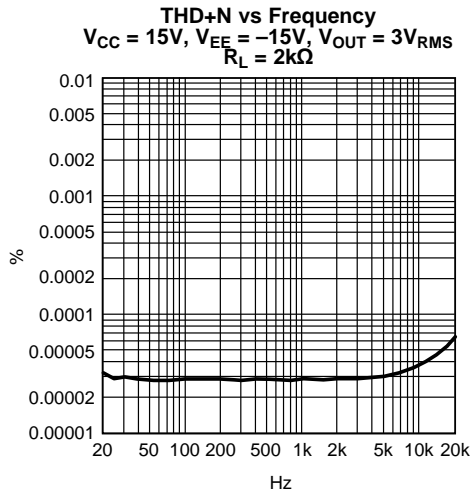


Figure 15.

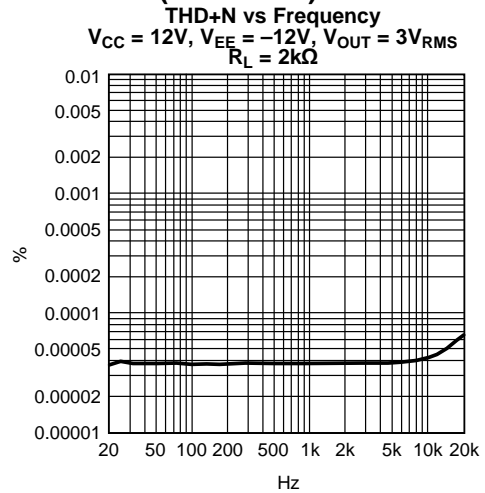


Figure 16.

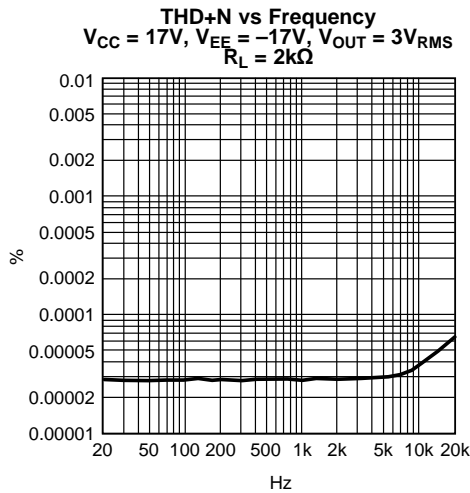


Figure 17.

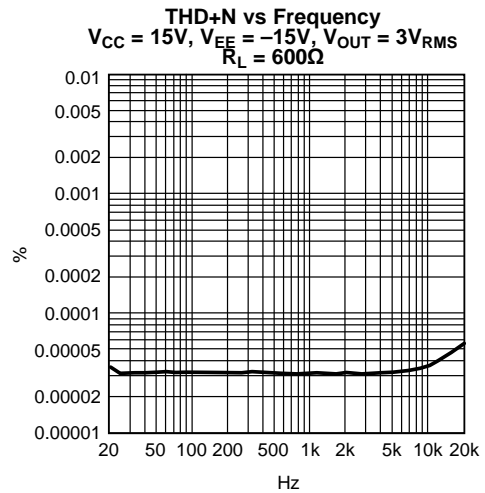


Figure 18.

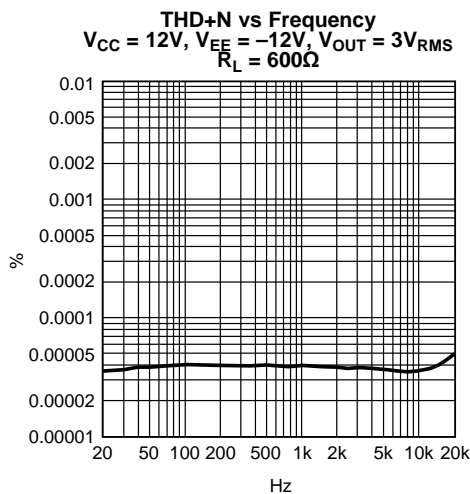


Figure 19.

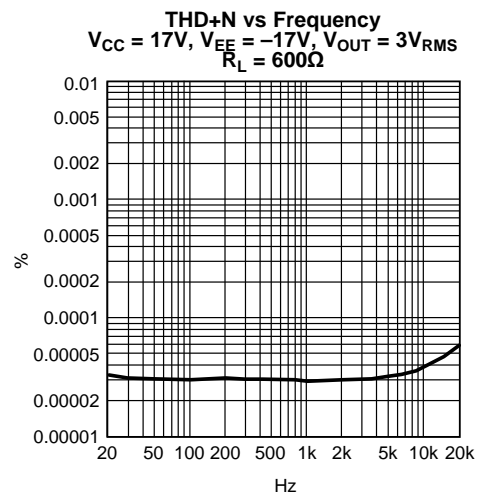
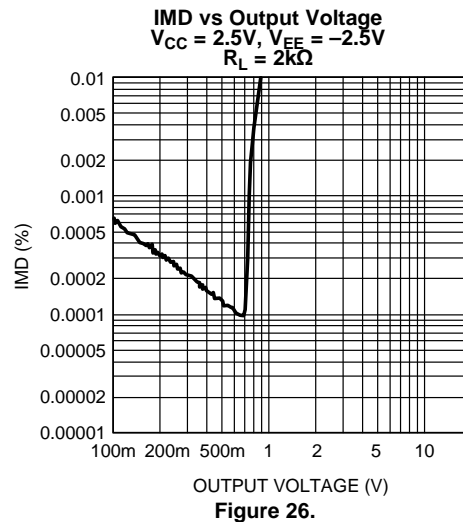
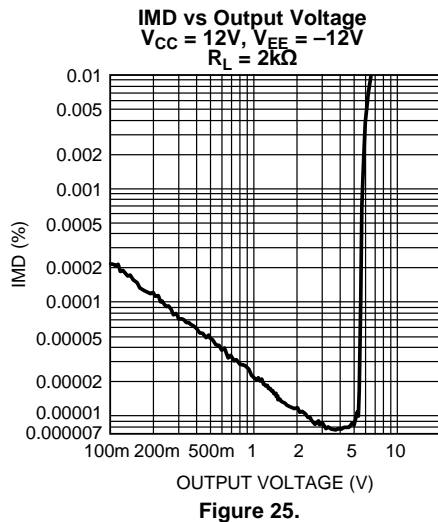
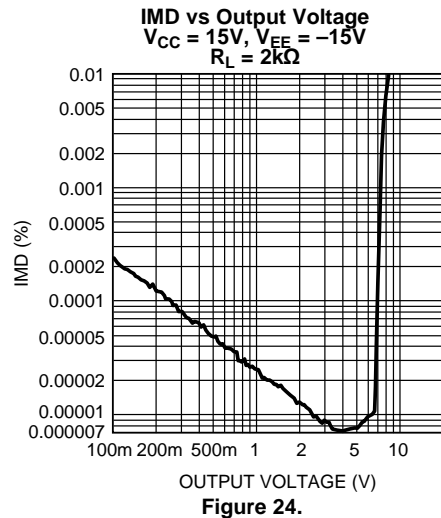
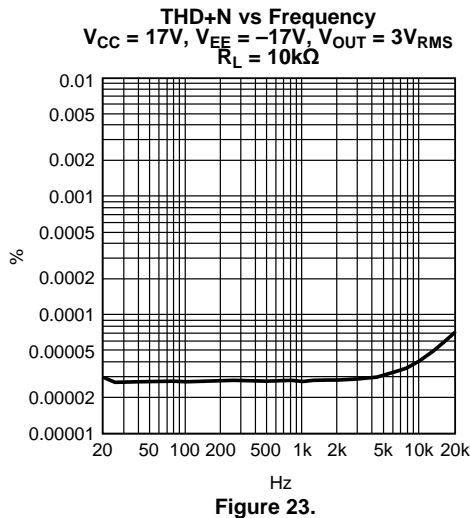
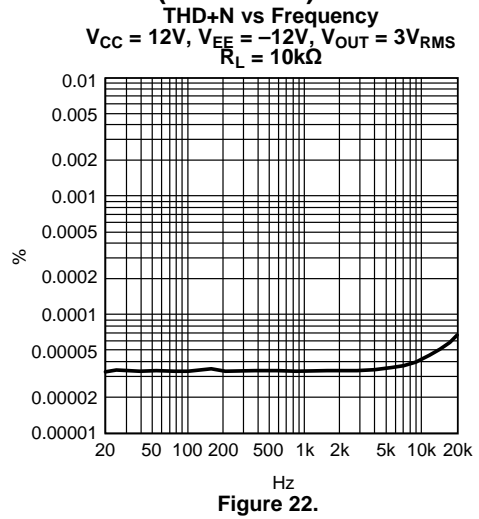
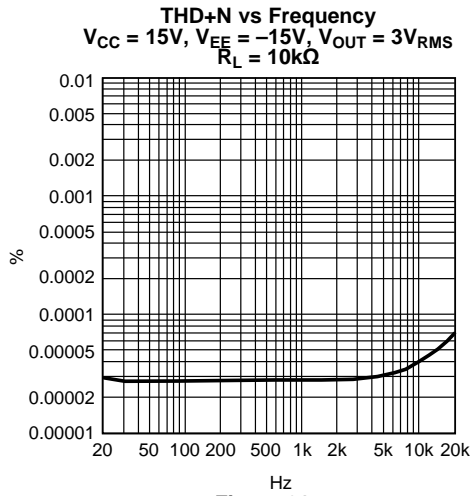


Figure 20.

**TYPICAL PERFORMANCE CHARACTERISTICS (continued)**





**TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

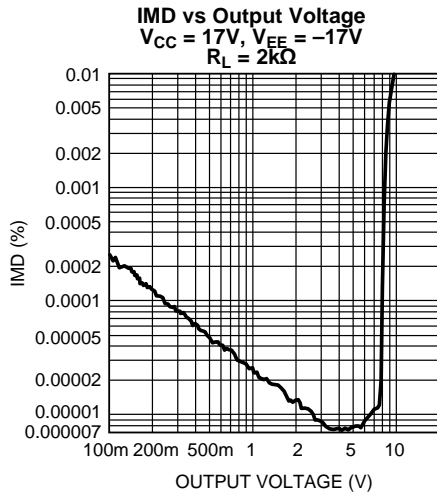


Figure 27.

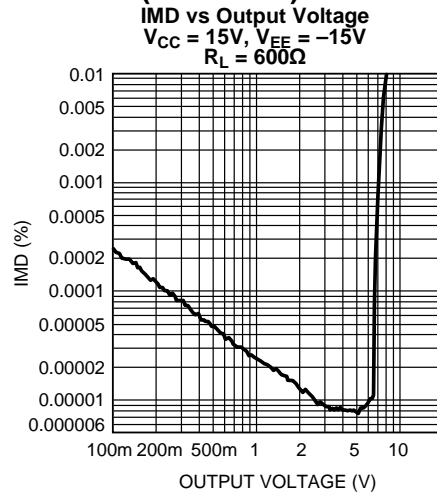


Figure 28.

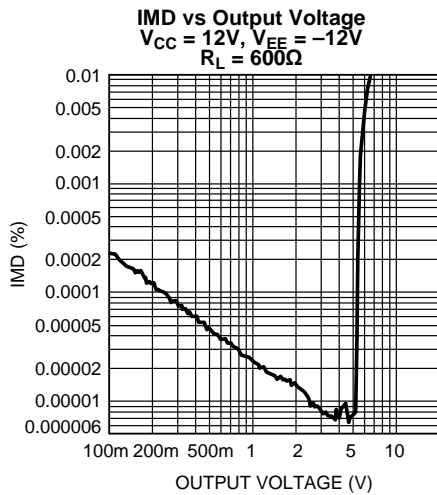


Figure 29.

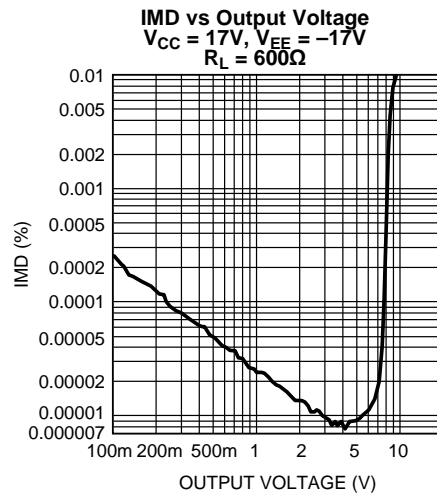


Figure 30.

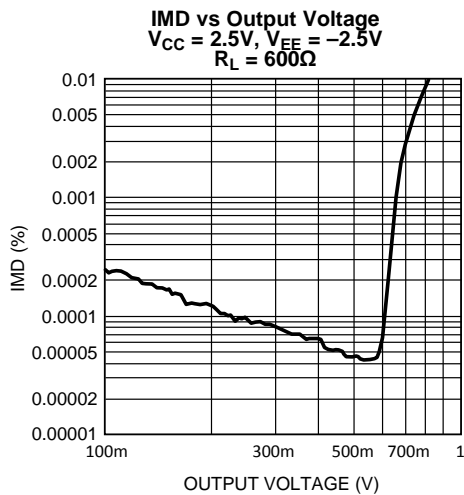


Figure 31.

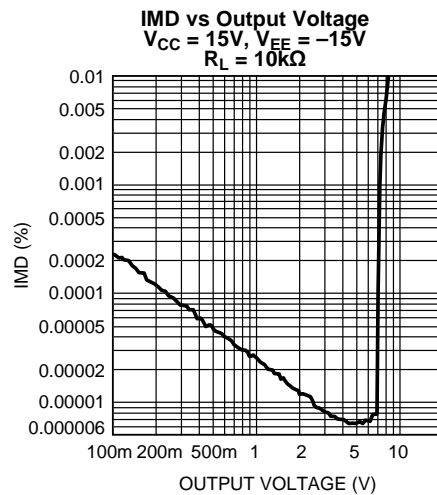


Figure 32.

**TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

**IMD vs Output Voltage**  
 $V_{CC} = 12V, V_{EE} = -12V$   
 $R_L = 10k\Omega$

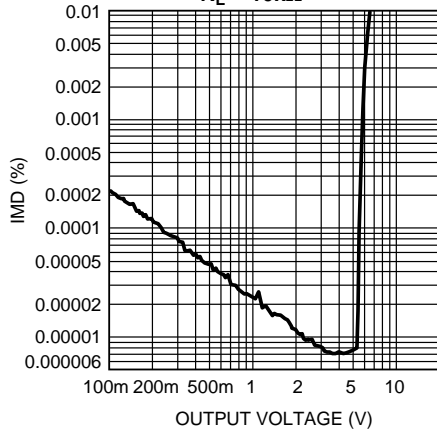


Figure 33.

**IMD vs Output Voltage**  
 $V_{CC} = 17V, V_{EE} = -17V$   
 $R_L = 10k\Omega$

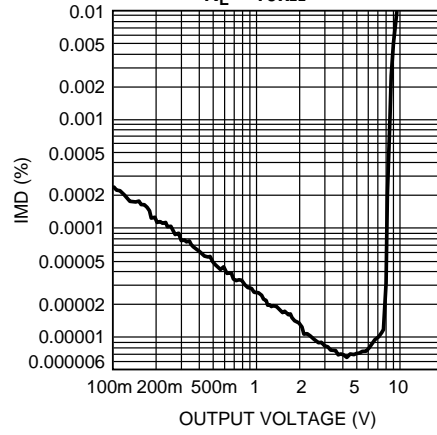


Figure 34.

**IMD vs Output Voltage**  
 $V_{CC} = 2.5V, V_{EE} = -2.5V$   
 $R_L = 10k\Omega$

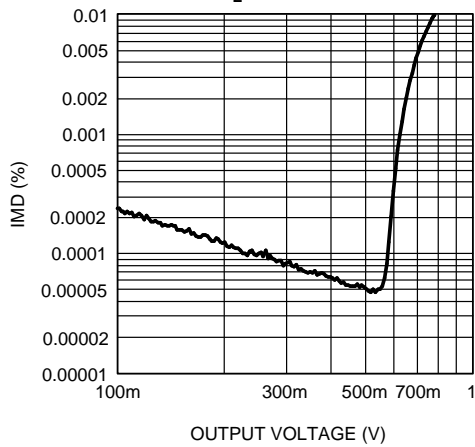


Figure 35.

**Voltage Noise Density vs Frequency**

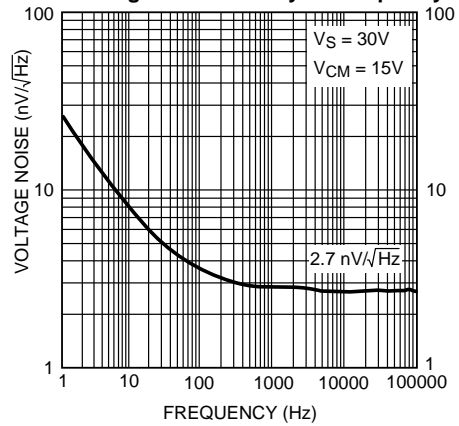


Figure 36.

**Current Noise Density vs Frequency**

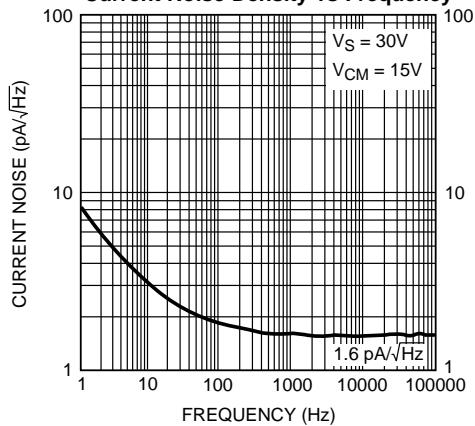


Figure 37.

**Crosstalk vs Frequency**  
 $V_{CC} = 15V, V_{EE} = -15V, V_{OUT} = 3V_{RMS}$   
 $A_V = 0dB, R_L = 2k\Omega$

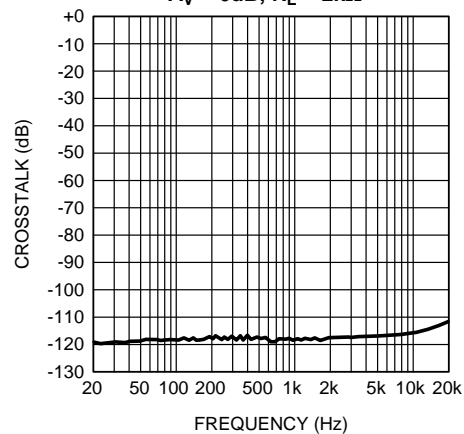


Figure 38.

**TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

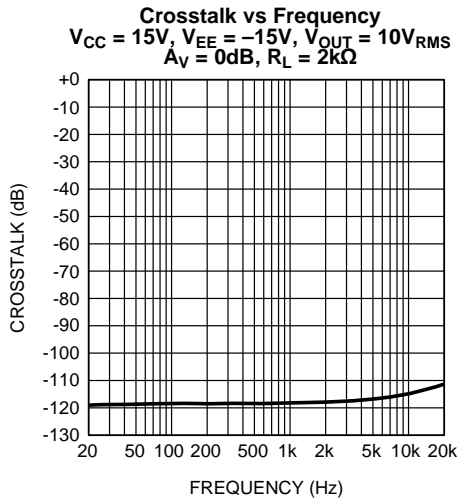


Figure 39.

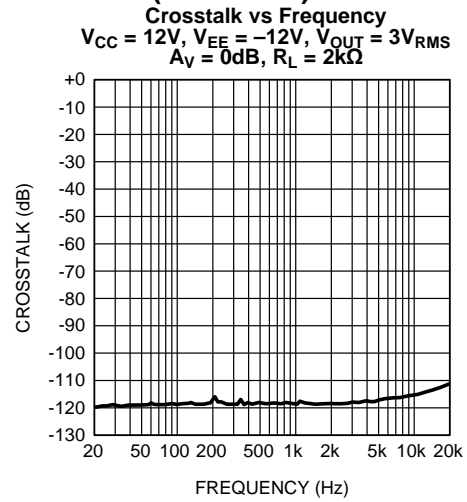


Figure 40.

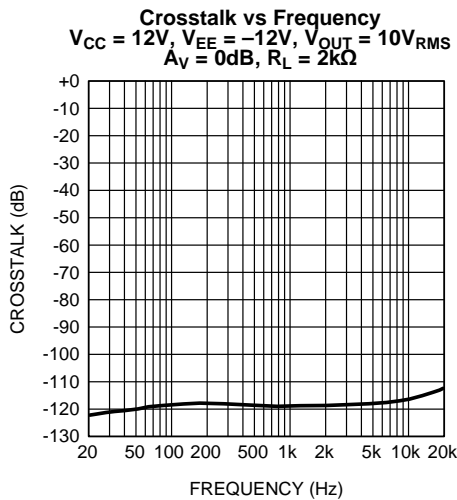


Figure 41.

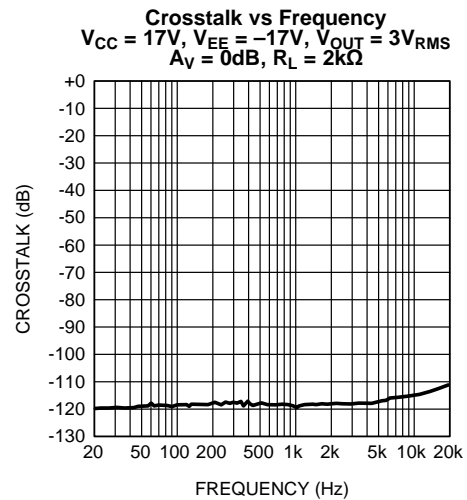


Figure 42.

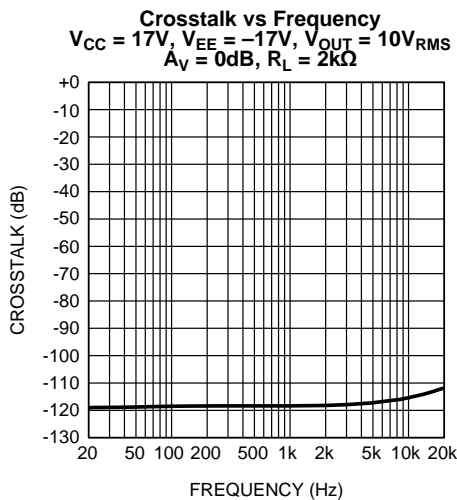


Figure 43.

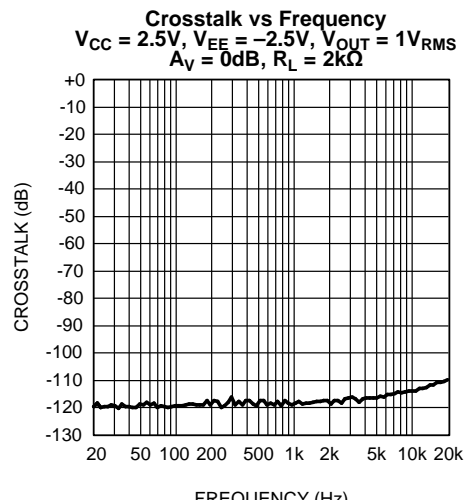


Figure 44.

**TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

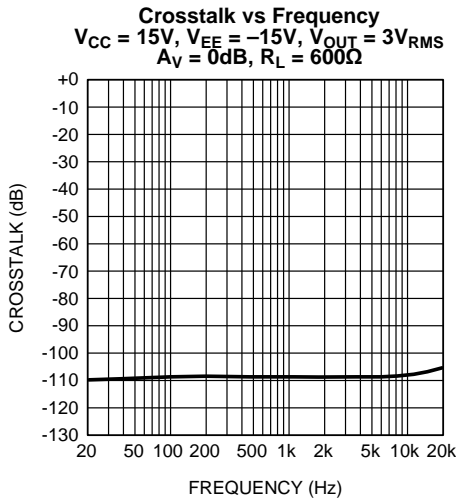


Figure 45.

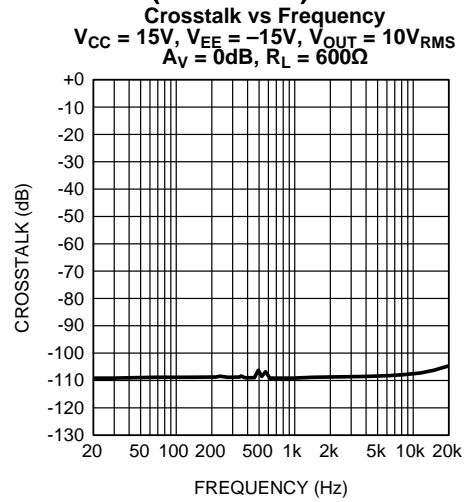


Figure 46.

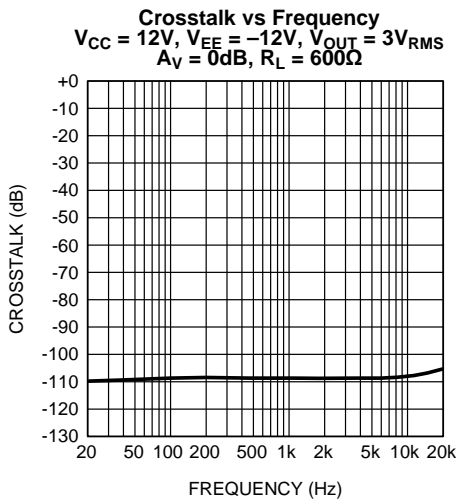


Figure 47.

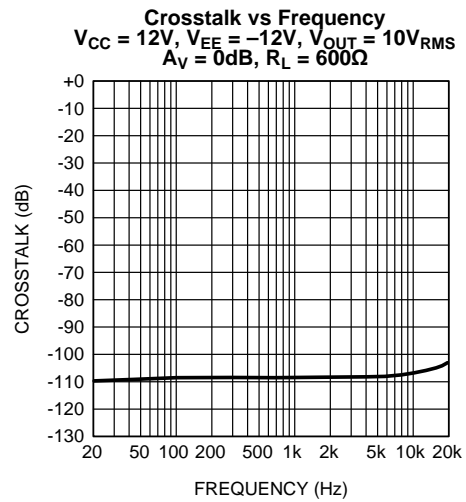


Figure 48.

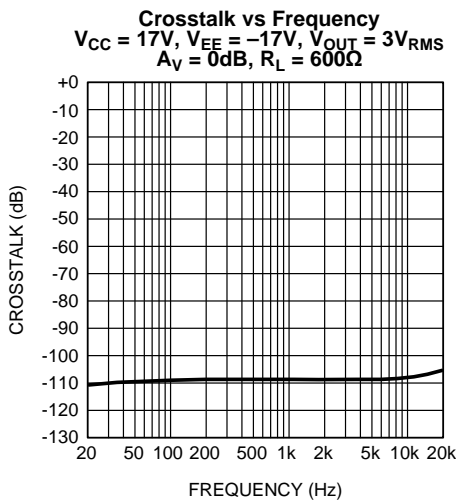


Figure 49.

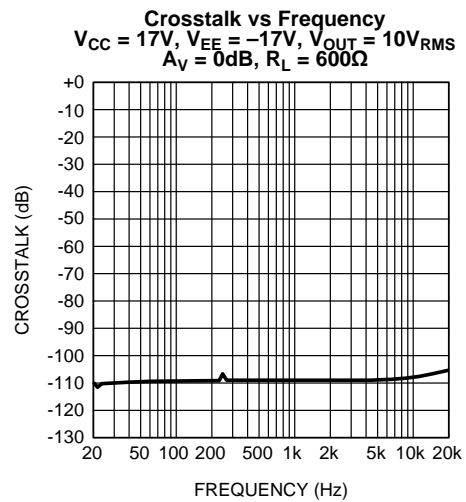


Figure 50.

**TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

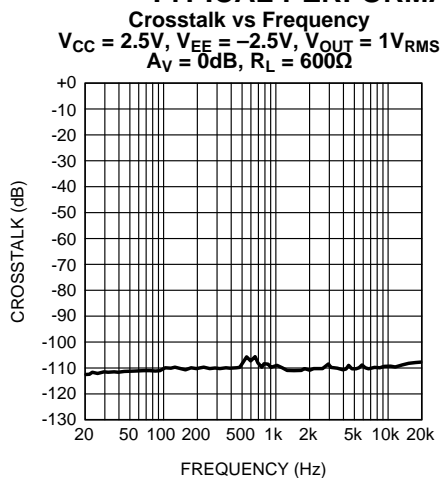


Figure 51.

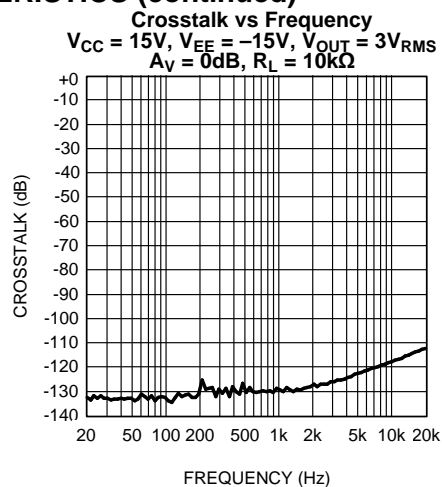


Figure 52.

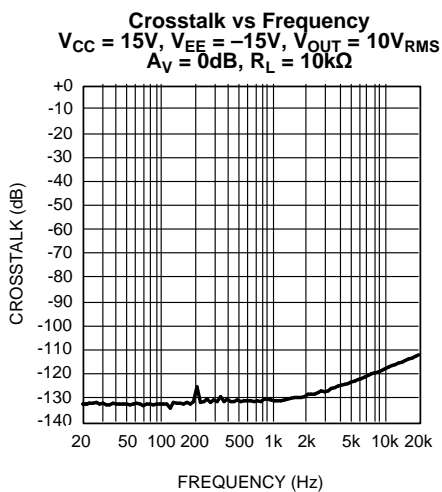


Figure 53.

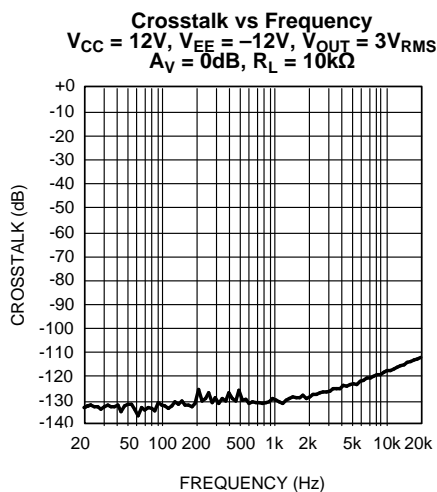


Figure 54.

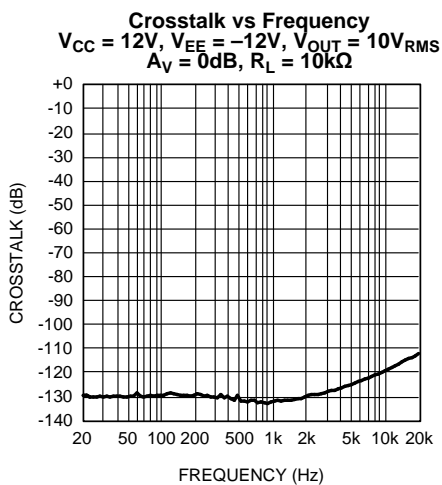


Figure 55.

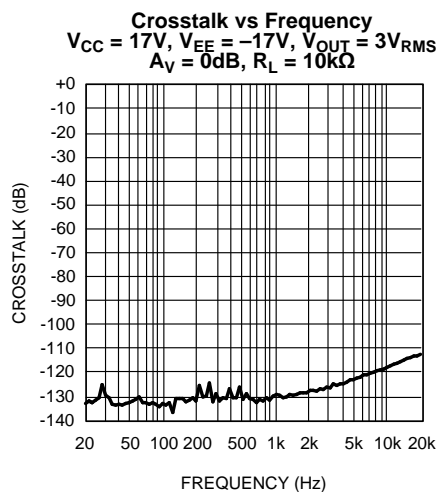


Figure 56.

**TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

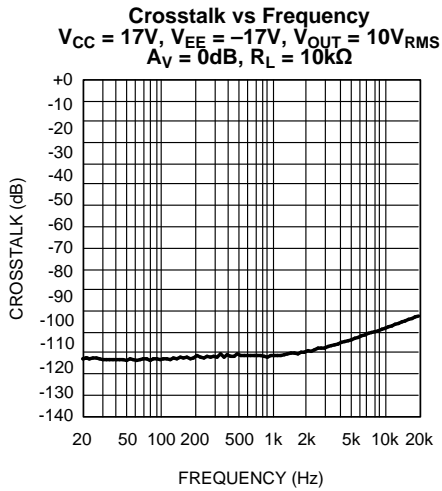


Figure 57.

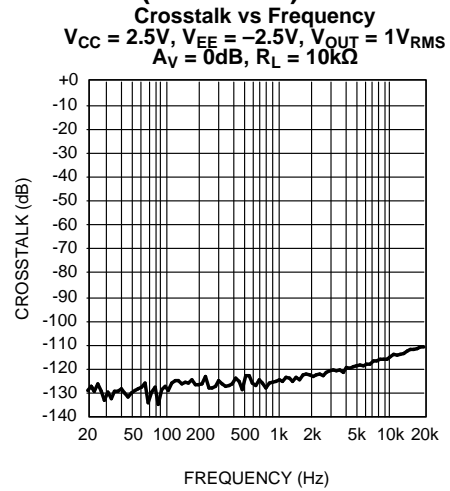


Figure 58.

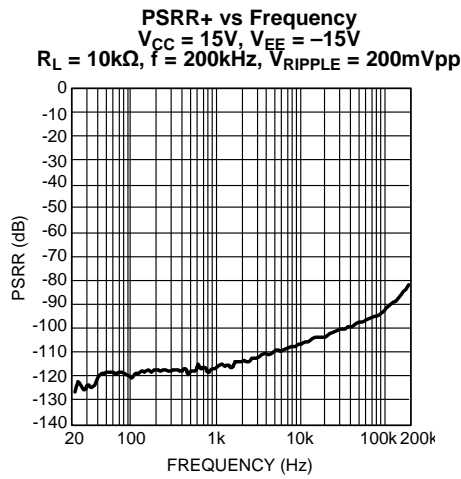


Figure 59.

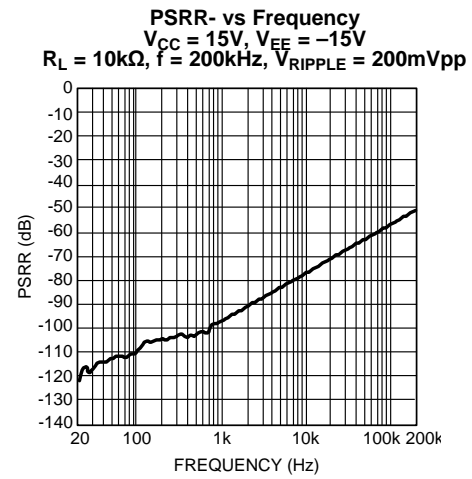


Figure 60.

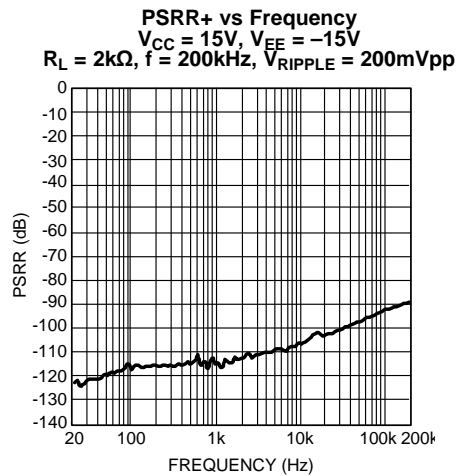


Figure 61.

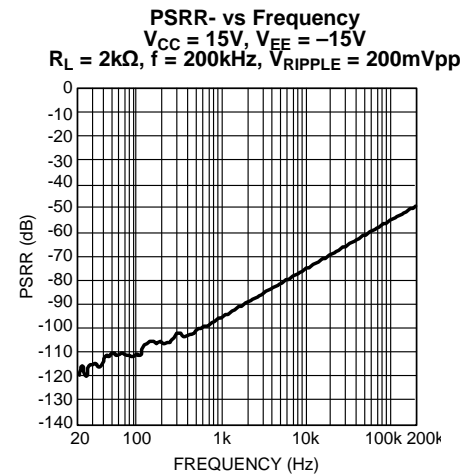


Figure 62.

**TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

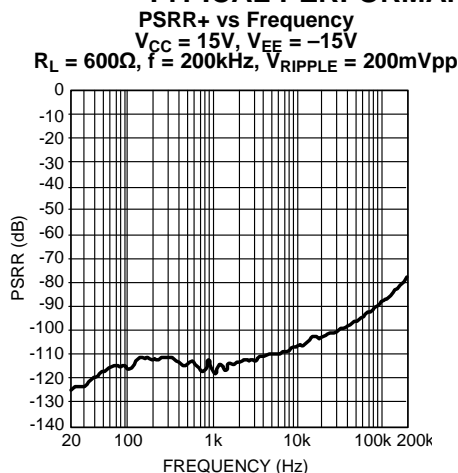


Figure 63.

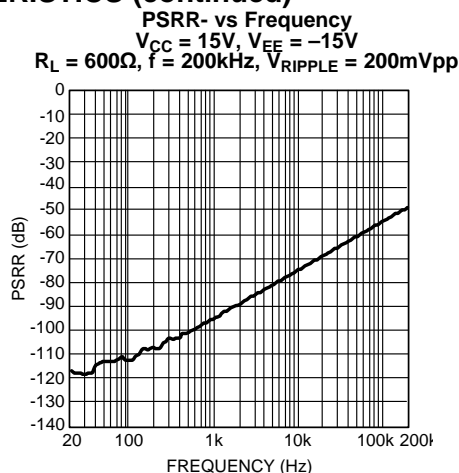


Figure 64.

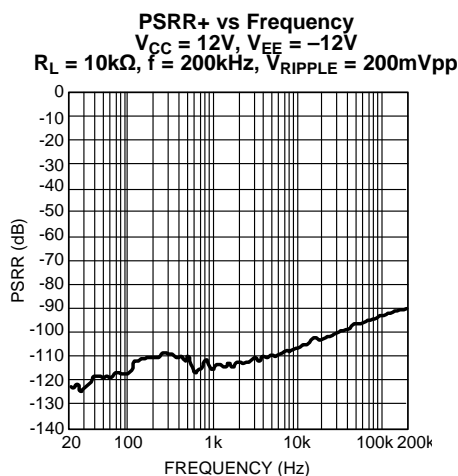


Figure 65.

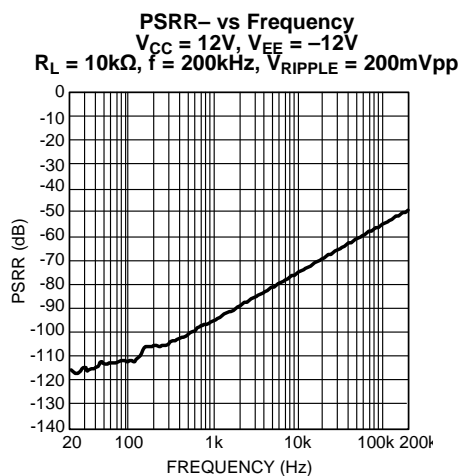


Figure 66.

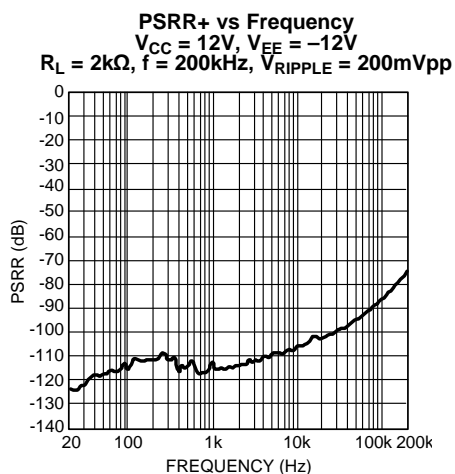


Figure 67.

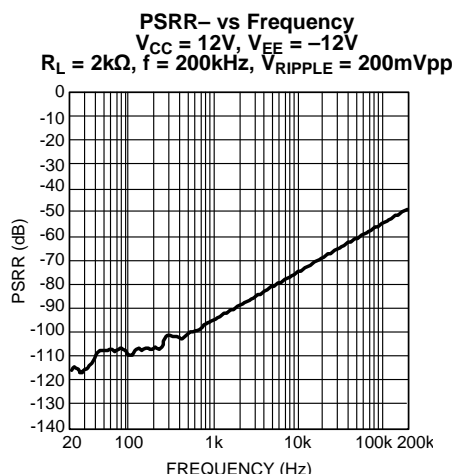


Figure 68.

**TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

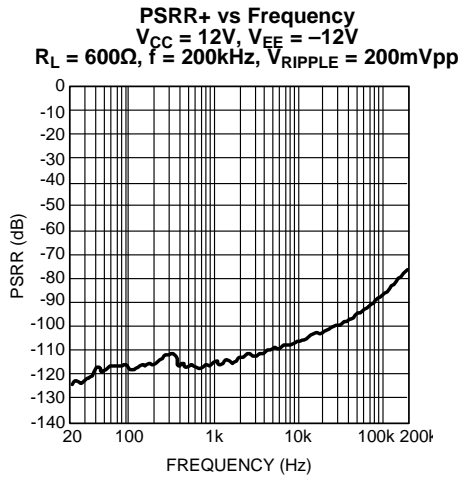


Figure 69.

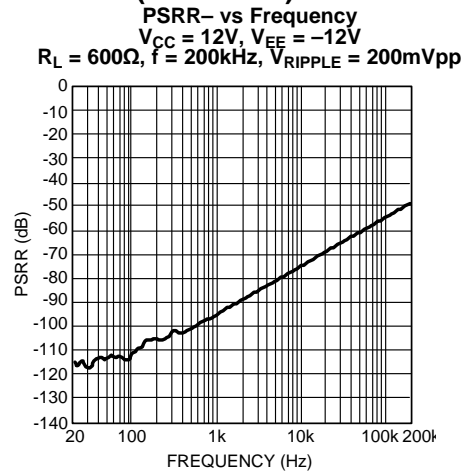


Figure 70.

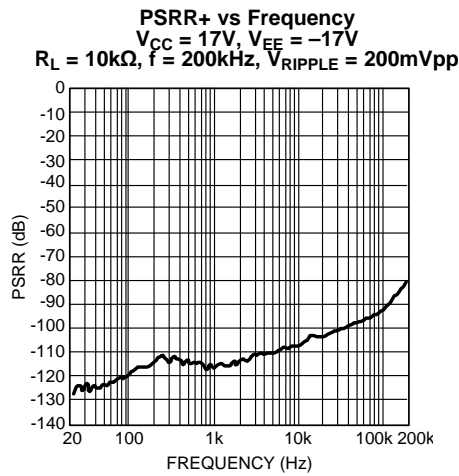


Figure 71.

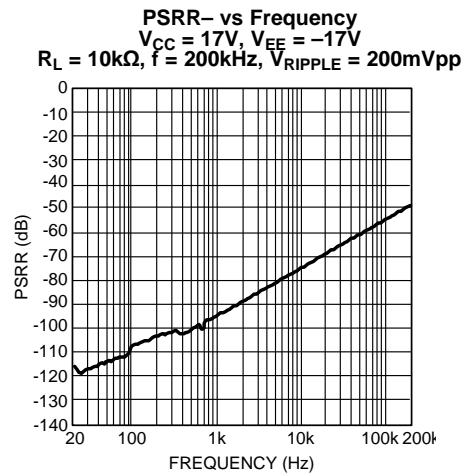


Figure 72.

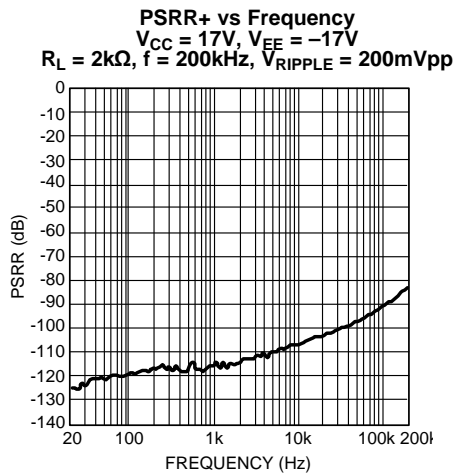


Figure 73.

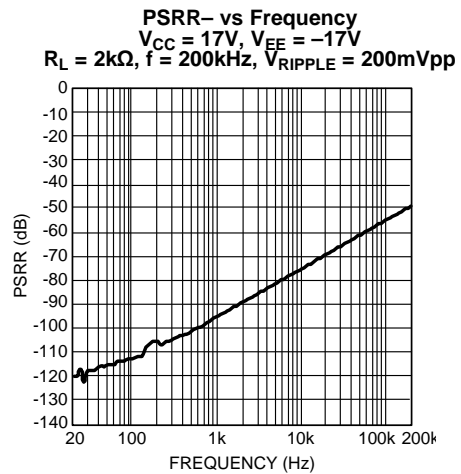


Figure 74.



**TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

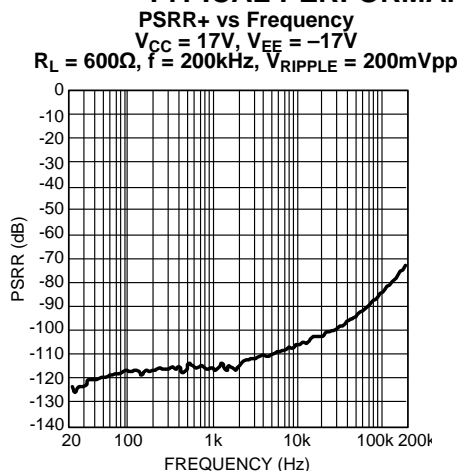


Figure 75.

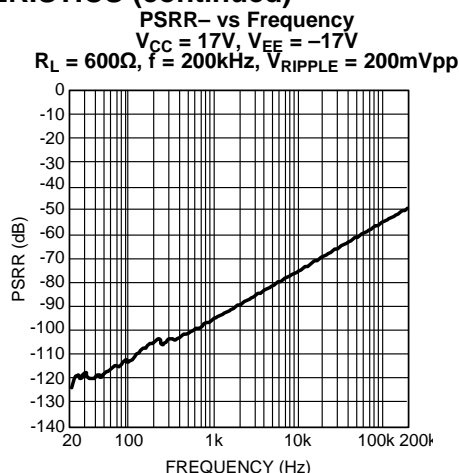


Figure 76.

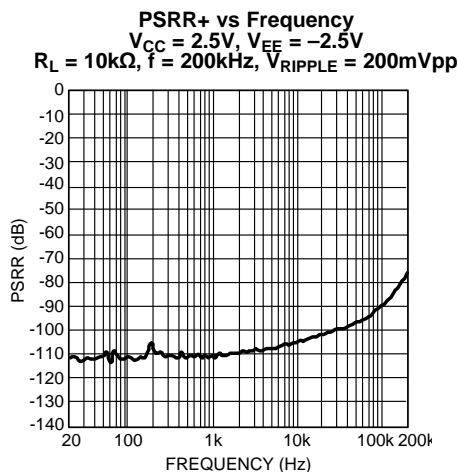


Figure 77.

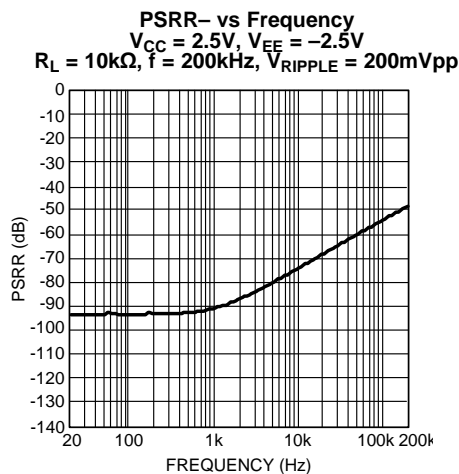


Figure 78.

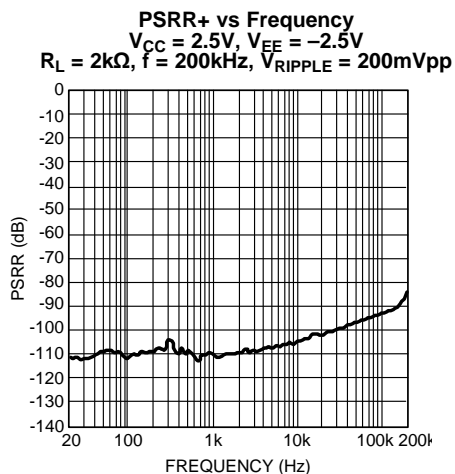


Figure 79.

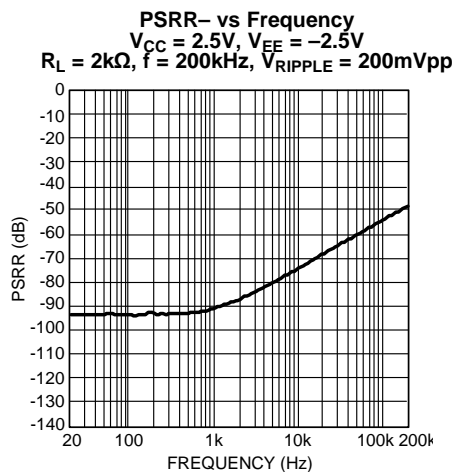


Figure 80.

**TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

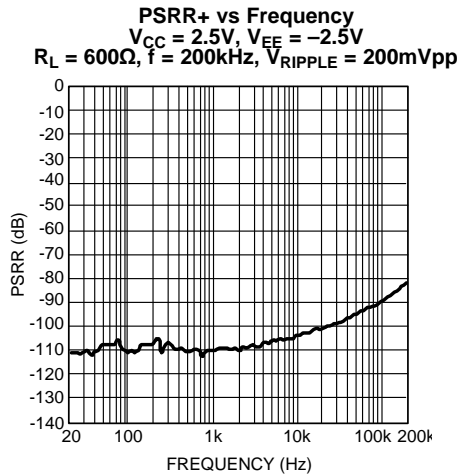


Figure 81.

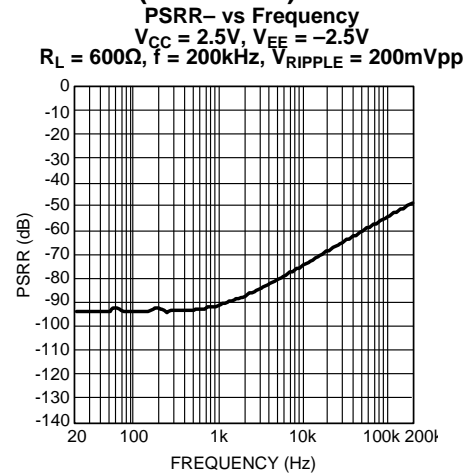


Figure 82.

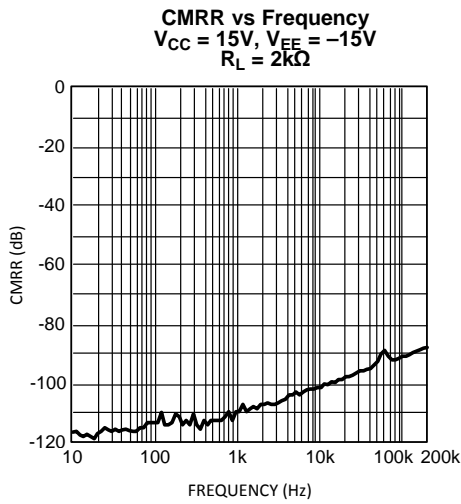


Figure 83.

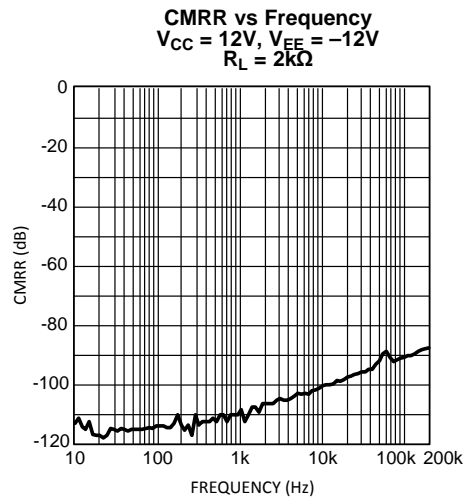


Figure 84.

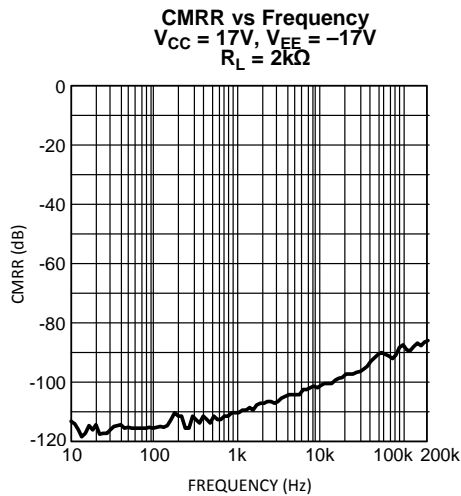


Figure 85.

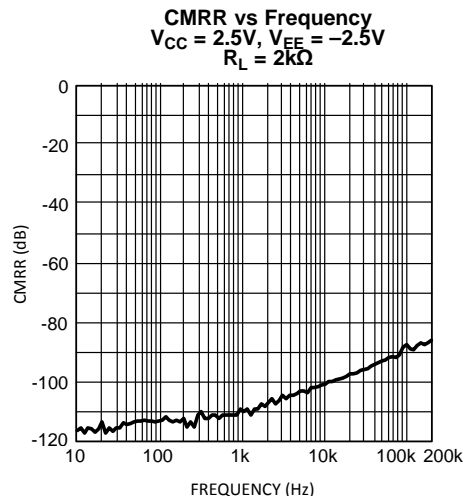


Figure 86.

**TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

**CMRR vs Frequency**  
 $V_{CC} = 15V, V_{EE} = -15V$   
 $R_L = 600\Omega$

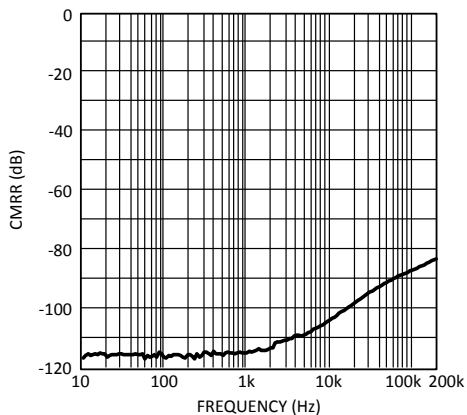


Figure 87.

**CMRR vs Frequency**  
 $V_{CC} = 12V, V_{EE} = -12V$   
 $R_L = 600\Omega$

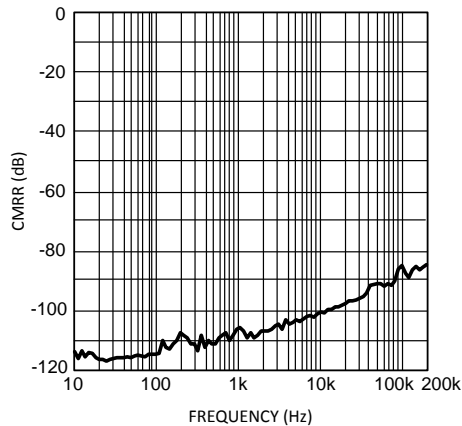


Figure 88.

**CMRR vs Frequency**  
 $V_{CC} = 17V, V_{EE} = -17V$   
 $R_L = 600\Omega$

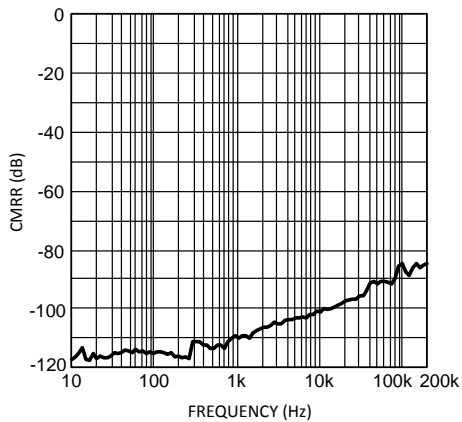


Figure 89.

**CMRR vs Frequency**  
 $V_{CC} = 2.5V, V_{EE} = -2.5V$   
 $R_L = 600\Omega$

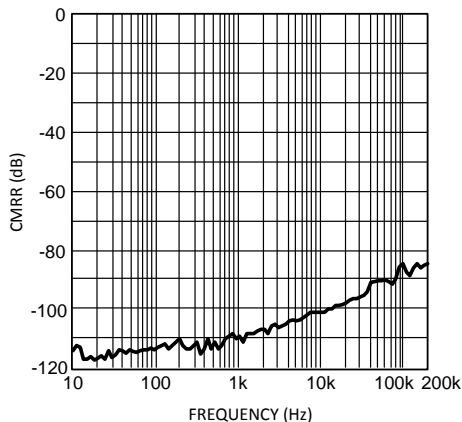


Figure 90.

**CMRR vs Frequency**  
 $V_{CC} = 15V, V_{EE} = -15V$   
 $R_L = 10k\Omega$

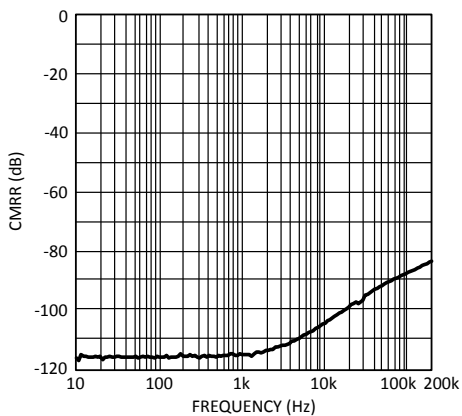


Figure 91.

**CMRR vs Frequency**  
 $V_{CC} = 12V, V_{EE} = -12V$   
 $R_L = 10k\Omega$

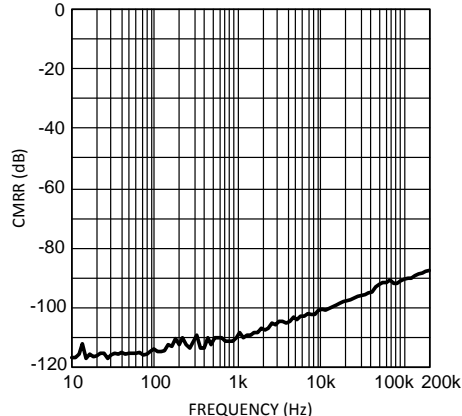


Figure 92.

**TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

**CMRR vs Frequency**  
 $V_{CC} = 17V, V_{EE} = -17V$   
 $R_L = 10k\Omega$

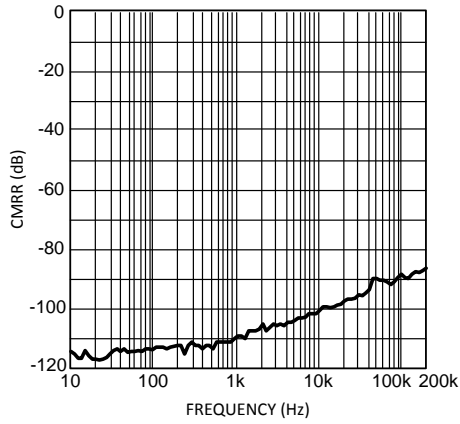


Figure 93.

**CMRR vs Frequency**  
 $V_{CC} = 2.5V, V_{EE} = -2.5V$   
 $R_L = 10k\Omega$

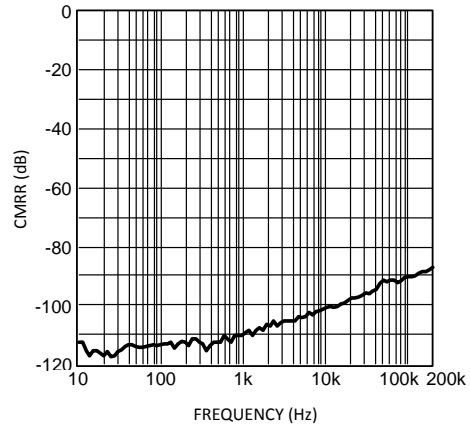


Figure 94.

**Output Voltage vs Load Resistance**  
 $V_{DD} = 15V, V_{EE} = -15V$   
 $THD+N = 1\%$

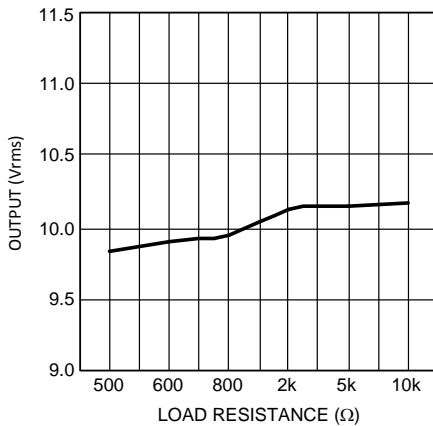


Figure 95.

**Output Voltage vs Load Resistance**  
 $V_{DD} = 12V, V_{EE} = -12V$   
 $THD+N = 1\%$

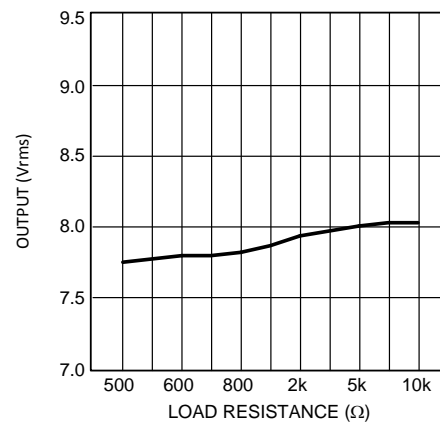


Figure 96.

**Output Voltage vs Load Resistance**  
 $V_{DD} = 17V, V_{EE} = -17V$   
 $THD+N = 1\%$

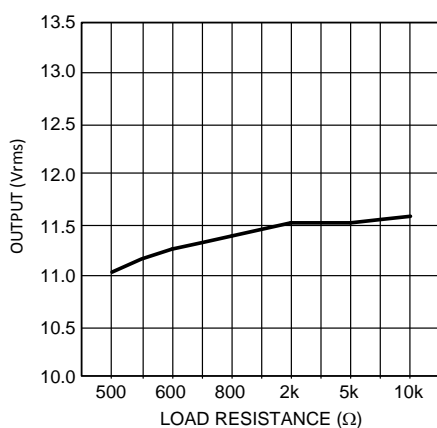


Figure 97.

**Output Voltage vs Load Resistance**  
 $V_{DD} = 2.5V, V_{EE} = -2.5V$   
 $THD+N = 1\%$

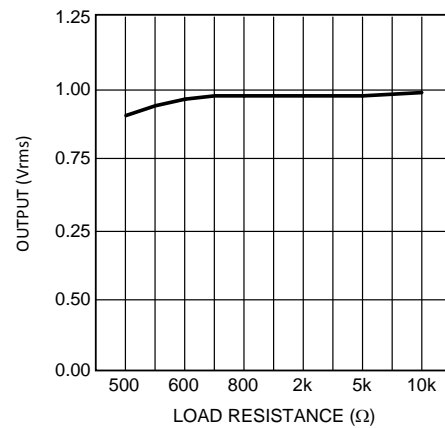


Figure 98.

**TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

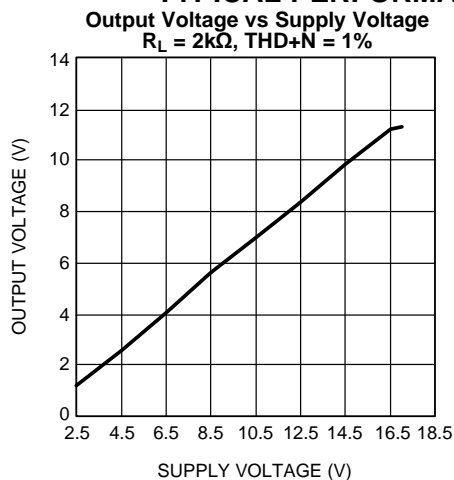


Figure 99.

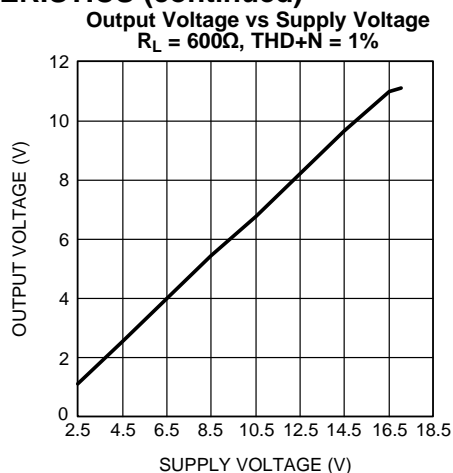


Figure 100.

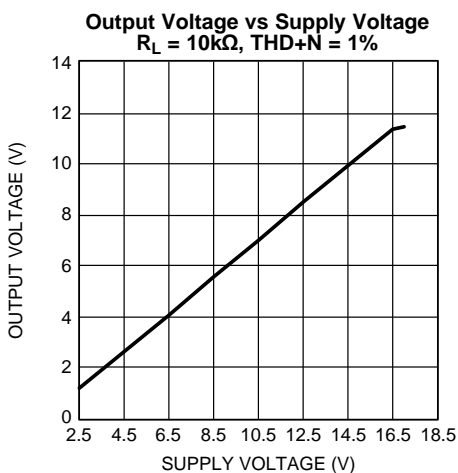


Figure 101.

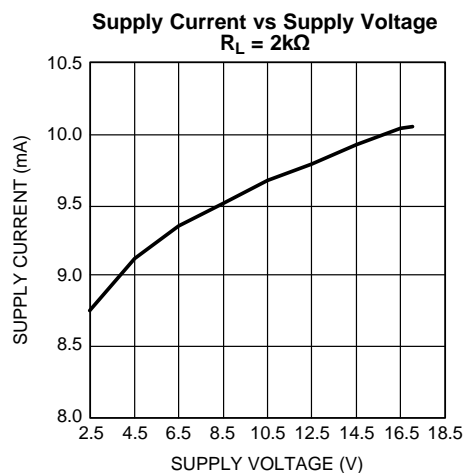


Figure 102.

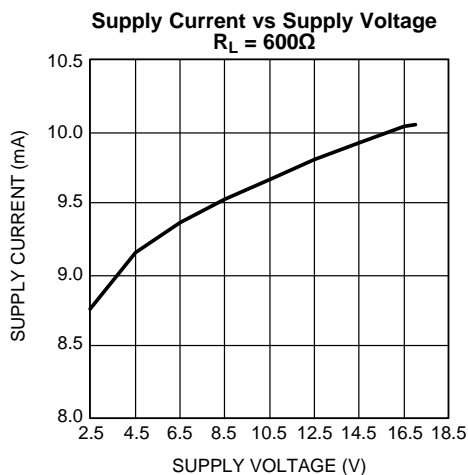


Figure 103.

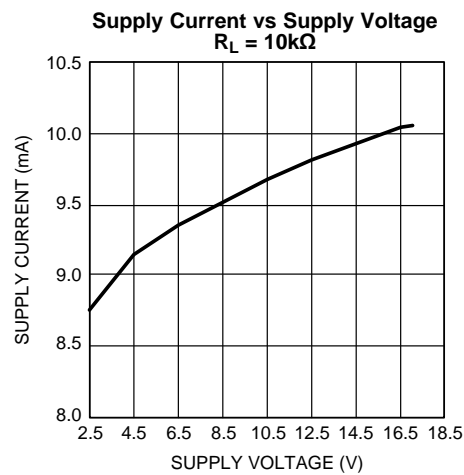


Figure 104.

**TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

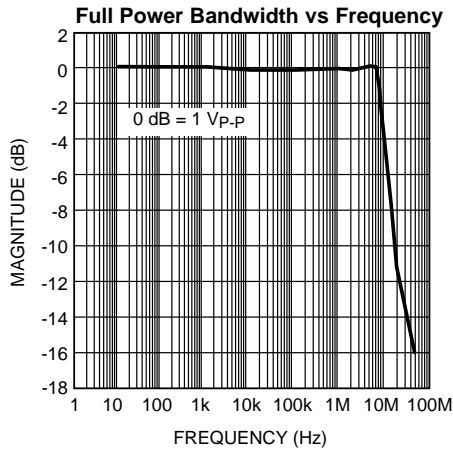


Figure 105.

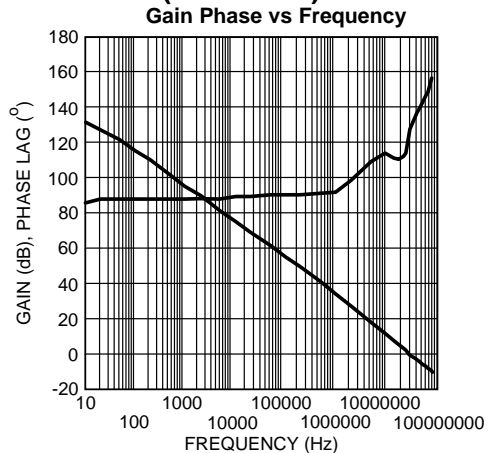


Figure 106.

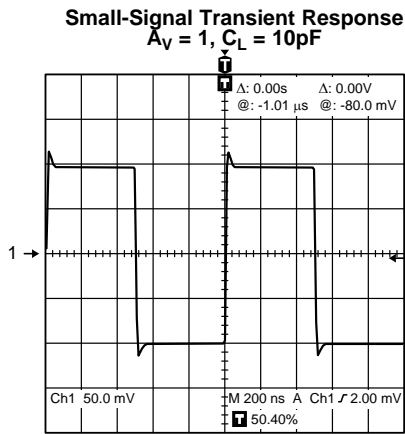


Figure 107.

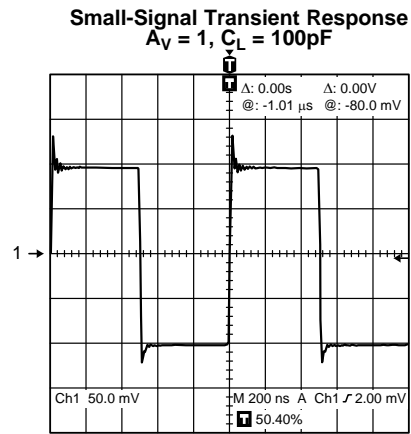


Figure 108.

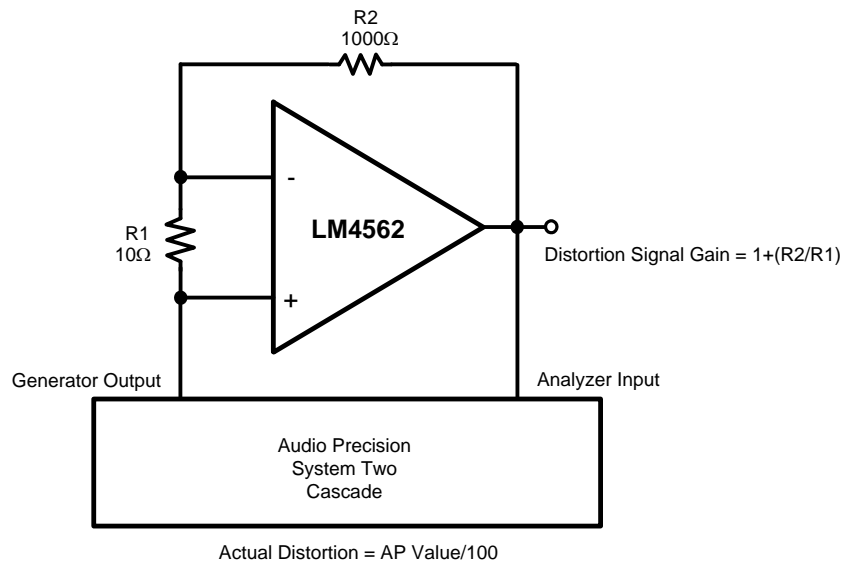
## APPLICATION INFORMATION

### DISTORTION MEASUREMENTS

The vanishingly low residual distortion produced by LM4562 is below the capabilities of all commercially available equipment. This makes distortion measurements just slightly more difficult than simply connecting a distortion meter to the amplifier's inputs and outputs. The solution, however, is quite simple: an additional resistor. Adding this resistor extends the resolution of the distortion measurement equipment.

The LM4562's low residual distortion is an input referred internal error. As shown in Figure 109, adding the 10Ω resistor connected between the amplifier's inverting and non-inverting inputs changes the amplifier's noise gain. The result is that the error signal (distortion) is amplified by a factor of 101. Although the amplifier's closed-loop gain is unaltered, the feedback available to correct distortion errors is reduced by 101, which means that measurement resolution increases by 101. To ensure minimum effects on distortion measurements, keep the value of R1 low as shown in Figure 109.

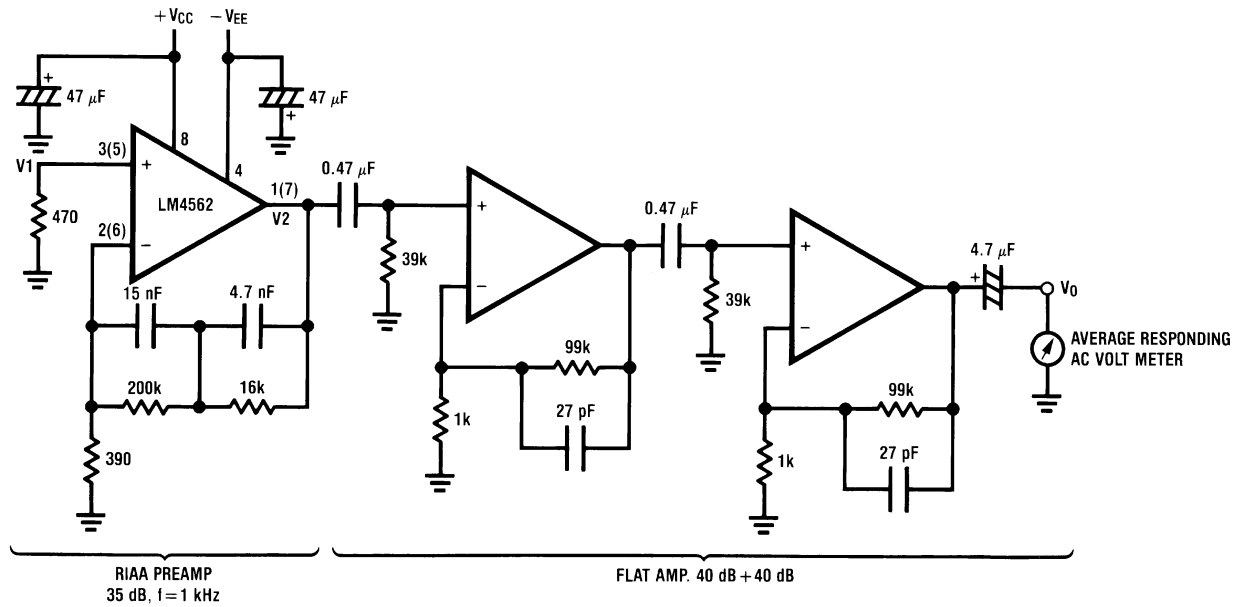
This technique is verified by duplicating the measurements with high closed loop gain and/or making the measurements at high frequencies. Doing so produces distortion components that are within the measurement equipment's capabilities. This datasheet's THD+N and IMD values were generated using the above described circuit connected to an Audio Precision System Two Cascade.



**Figure 109. THD+N and IMD Distortion Test Circuit**

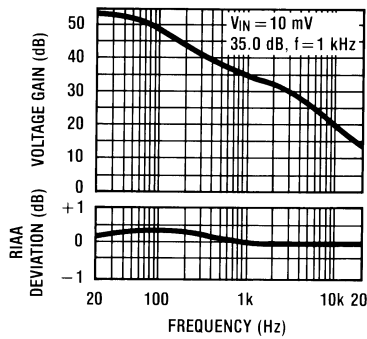
The LM4562 is a high-speed op amp with excellent phase margin and stability. Capacitive loads up to 100pF will cause little change in the phase characteristics of the amplifiers and are therefore allowable.

Capacitive loads greater than 100pF must be isolated from the output. The most straightforward way to do this is to put a resistor in series with the output. This resistor will also prevent excess power dissipation if the output is accidentally shorted.

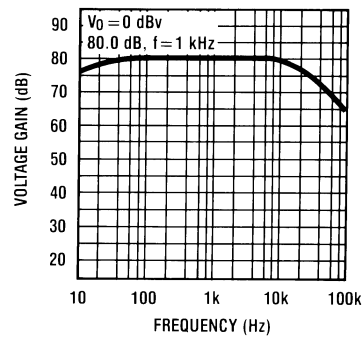


- A. Complete shielding is required to prevent induced pick up from external sources. Always check with oscilloscope for power line noise.

**Figure 110. Noise Measurement Circuit**  
**Total Gain: 115 dB @ f = 1 kHz**  
**Input Referred Noise Voltage:  $e_n = V_0/560,000$  (V)**



**Figure 111. RIAA Preamp Voltage Gain, RIAA Deviation vs Frequency**



**Figure 112. Flat Amp Voltage Gain vs Frequency**



Evaluation Module Schematic

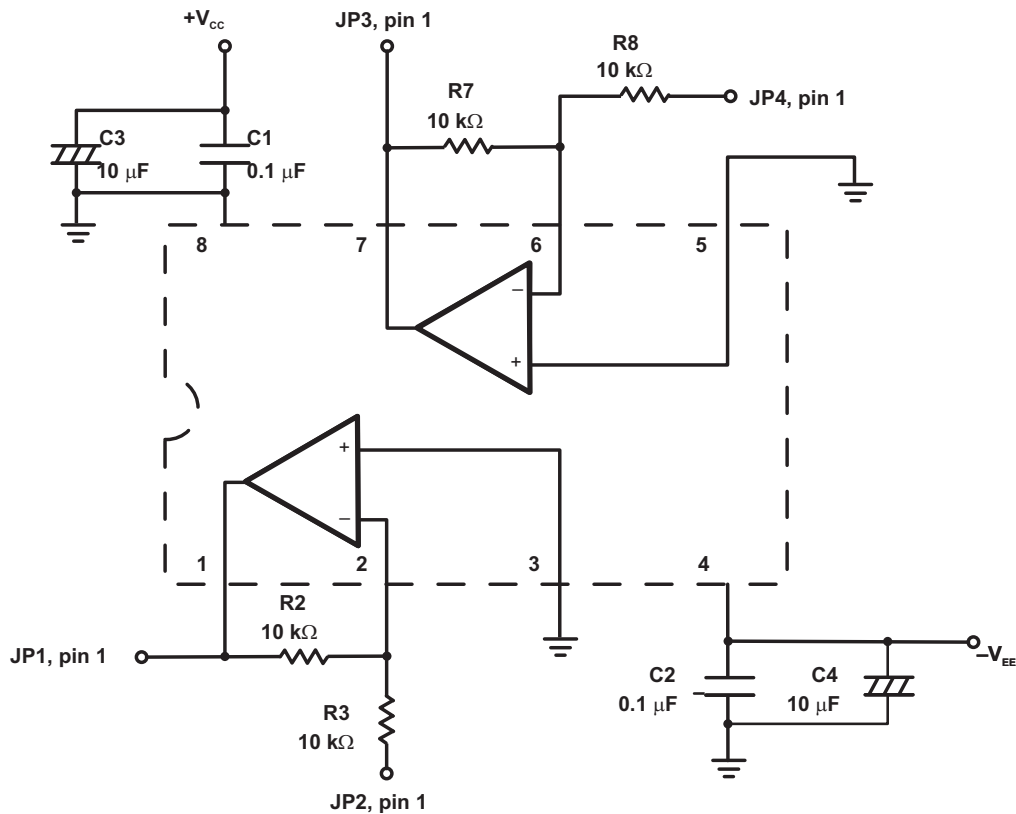
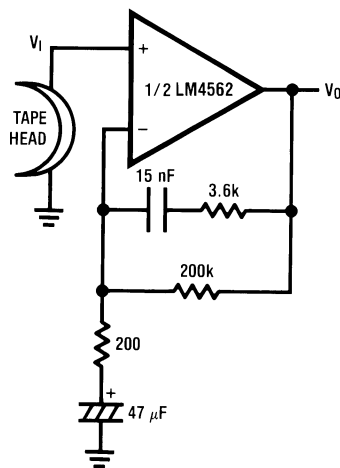


Figure 113. Inverting Amplifiers

Typical Applications



$A_V = 34.5$   
 $F = 1 \text{ kHz}$   
 $E_n = 0.38 \mu\text{V}$   
 A Weighted

Figure 114. NAB Preamp

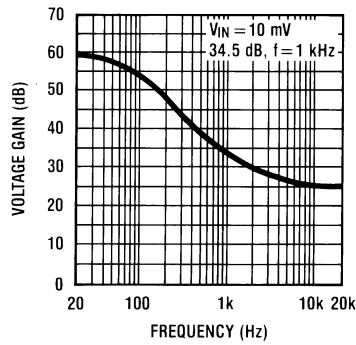
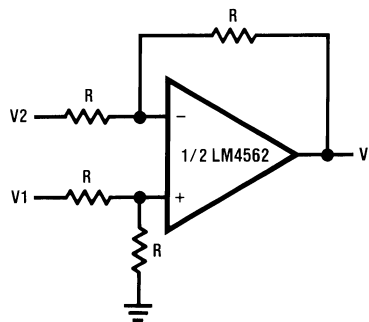
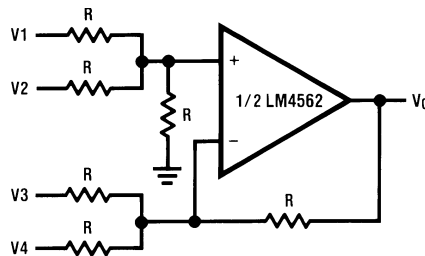


Figure 115. NAB Preamp Voltage Gain vs Frequency



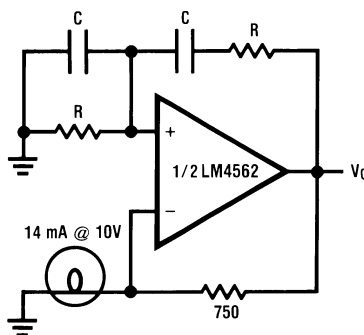
$$V_O = V_1 - V_2$$

Figure 116. Balanced to Single-Ended Converter



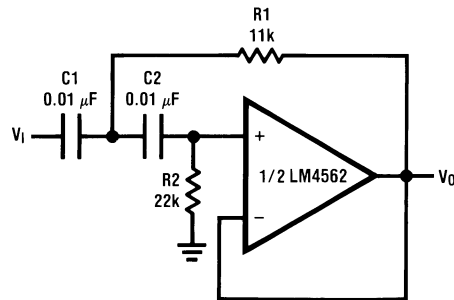
$$V_O = V_1 + V_2 - V_3 - V_4$$

Figure 117. Adder/Subtractor



$$f_o = \frac{1}{2\pi RC}$$

Figure 118. Sine Wave Oscillator



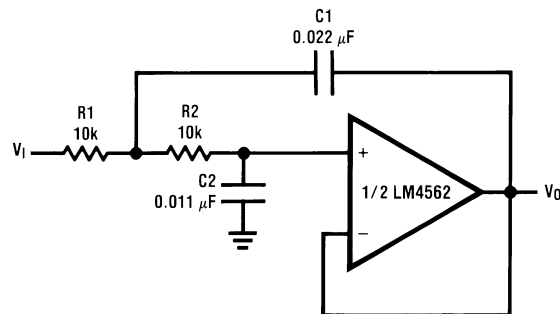
if  $C1 = C2 = C$

$$R1 = \frac{\sqrt{2}}{2\omega_0 C}$$

$$R2 = 2 \cdot R1$$

Illustration is  $f_0 = 1 \text{ kHz}$

**Figure 119. Second-Order High-Pass Filter (Butterworth)**



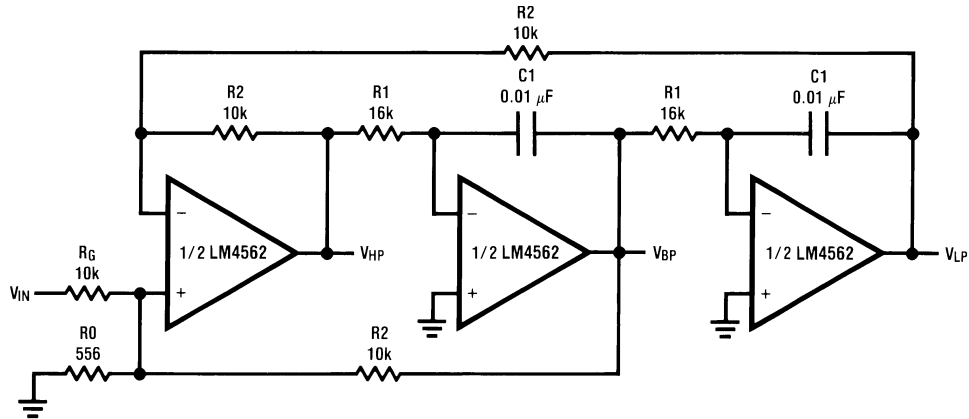
if  $R1 = R2 = R$

$$C1 = \frac{\sqrt{2}}{\omega_0 R}$$

$$C2 = \frac{C1}{2}$$

Illustration is  $f_0 = 1 \text{ kHz}$

**Figure 120. Second-Order Low-Pass Filter (Butterworth)**



$$f_0 = \frac{1}{2\pi C1 R1}, Q = \frac{1}{2} \left( 1 + \frac{R2}{R0} + \frac{R2}{RG} \right), A_{BP} = Q A_{LP} = Q A_{LH} = \frac{R2}{RG}$$

Illustration is  $f_0 = 1$  kHz,  $Q = 10$ ,  $A_{BP} = 1$

Figure 121. State Variable Filter

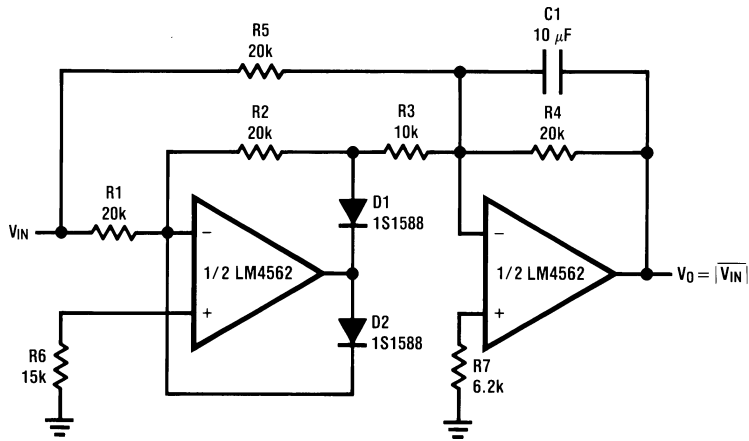


Figure 122. AC/DC Converter

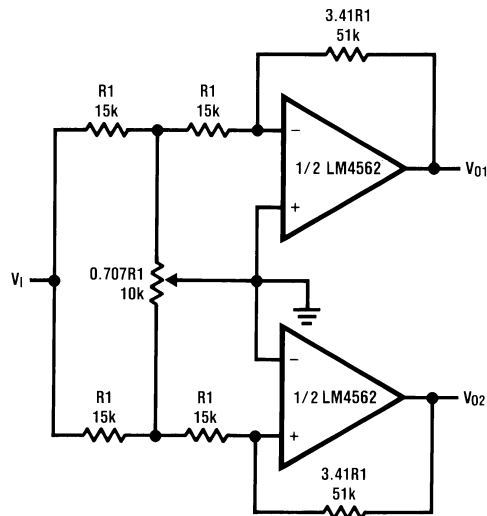


Figure 123. 2-Channel Panning Circuit (Pan Pot)

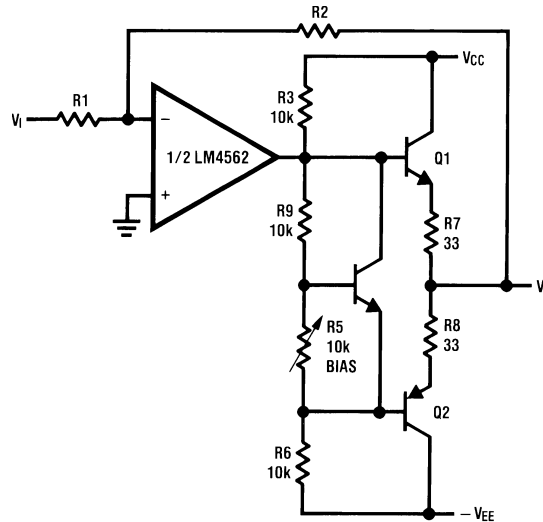
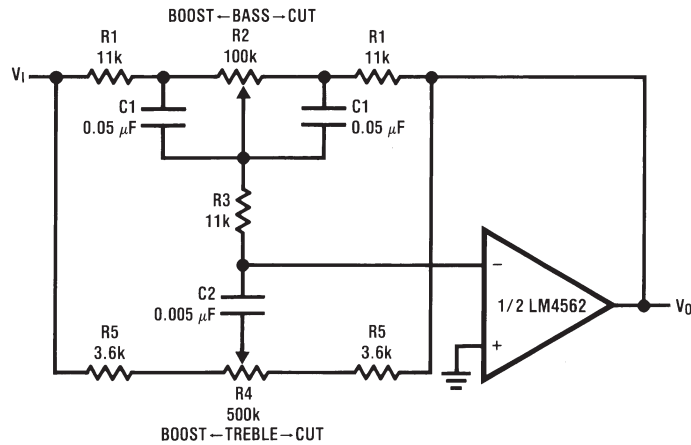


Figure 124. Line Driver



$$f_L \approx \frac{1}{2\pi R_2 C_1}, f_{LB} \approx \frac{1}{2\pi R_1 C_1}$$

$$f_H \approx \frac{1}{2\pi R_5 C_2}, f_{HB} \approx \frac{1}{2\pi (R_1 + R_5 + 2R_3) C_2}$$

The equations started above are simplifications, providing guidance of general -3dB point values, when the potentiometers are at their null position.

Illustration is:

$$f_L \approx 32 \text{ Hz}, f_{LB} \approx 320 \text{ Hz}$$

$$f_H \approx 11 \text{ kHz}, f_{HB} \approx 1.1 \text{ kHz}$$

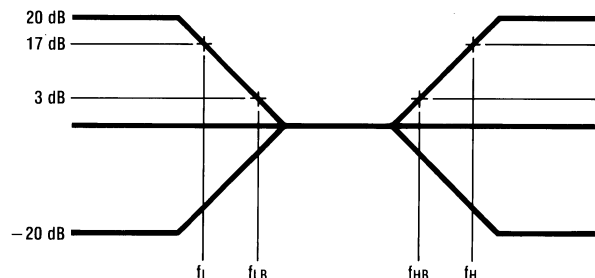
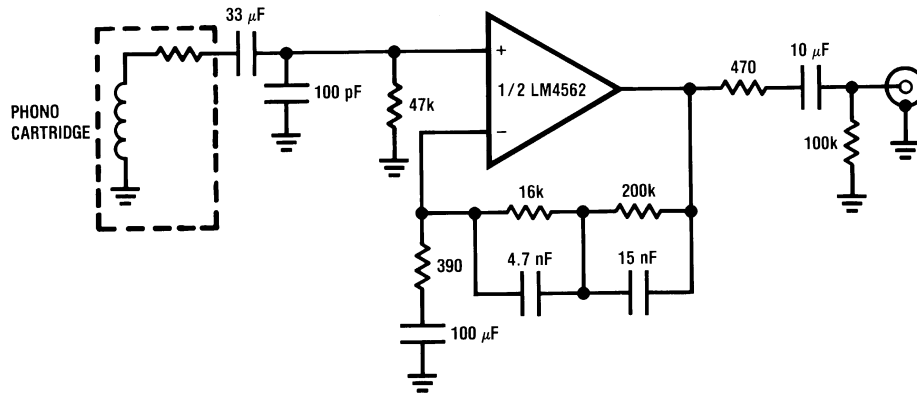
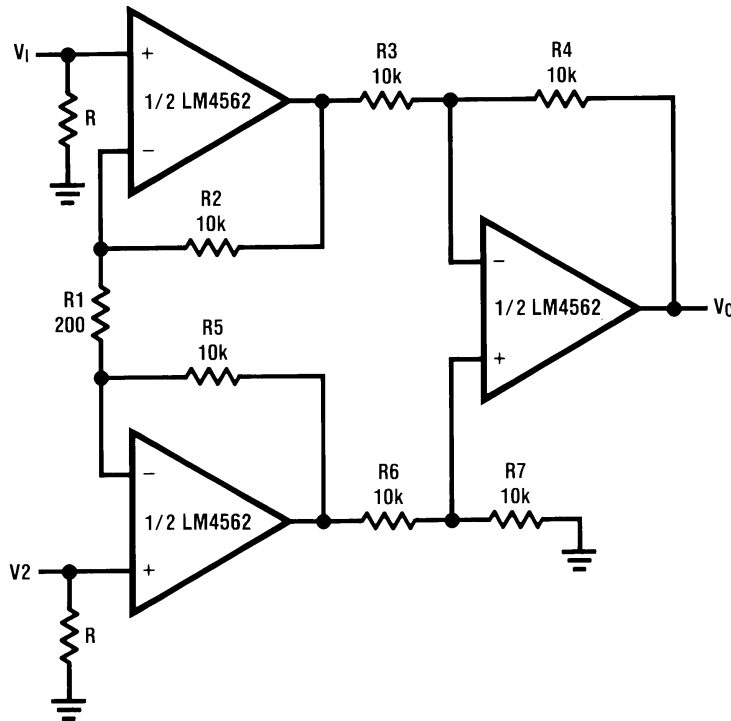


Figure 125. Tone Control



$A_v = 35 \text{ dB}$   
 $E_n = 0.33 \mu\text{V S/N} = 90 \text{ dB}$   
 $f = 1 \text{ kHz}$   
 A Weighted  
 A Weighted,  $V_{IN} = 10 \text{ mV}$   
 @  $f = 1 \text{ kHz}$

Figure 126. RIAA Preamp



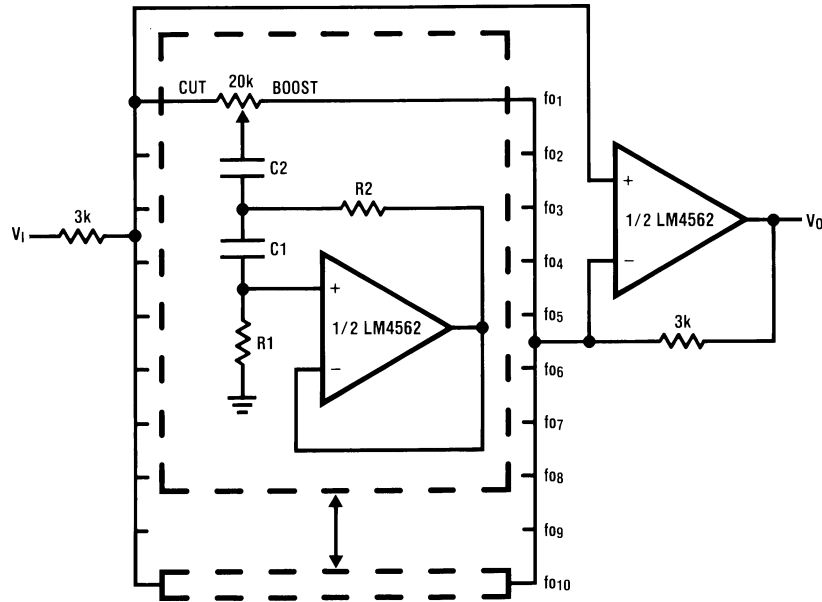
If  $R_2 = R_5, R_3 = R_6, R_4 = R_7$

$$V_0 = \left(1 + \frac{2R_2}{R_1}\right) \frac{R_4}{R_3} (V_2 - V_1)$$

Illustration is:

$$V_0 = 101(V_2 - V_1)$$

Figure 127. Balanced Input Mic Amp



A. See Table 1.

Figure 128. 10-Band Graphic Equalizer

Table 1.  $C_1$ ,  $C_2$ ,  $R_1$ , and  $R_2$  Values for Figure 128<sup>(1)</sup>

$f_o$ (Hz)	$C_1$	$C_2$	$R_1$	$R_2$
32	0.12 $\mu$ F	4.7 $\mu$ F	75k $\Omega$	500 $\Omega$
64	0.056 $\mu$ F	3.3 $\mu$ F	68k $\Omega$	510 $\Omega$
125	0.033 $\mu$ F	1.5 $\mu$ F	62k $\Omega$	510 $\Omega$
250	0.015 $\mu$ F	0.82 $\mu$ F	68k $\Omega$	470 $\Omega$
500	8200pF	0.39 $\mu$ F	62k $\Omega$	470 $\Omega$
1k	3900pF	0.22 $\mu$ F	68k $\Omega$	470 $\Omega$
2k	2000pF	0.1 $\mu$ F	68k $\Omega$	470 $\Omega$
4k	1100pF	0.056 $\mu$ F	62k $\Omega$	470 $\Omega$
8k	510pF	0.022 $\mu$ F	68k $\Omega$	510 $\Omega$
16k	330pF	0.012 $\mu$ F	51k $\Omega$	510 $\Omega$

(1) At volume of change =  $\pm 12$  dB Q = 1.7

## REVISION HISTORY

Changes from Revision J (April 2013) to Revision K	Page
• Added EVM schematic .....	<a href="#">25</a>



## REVISION HISTORY

Rev	Date	Description
1.0	08/16/06	Initial release.
1.1	08/22/06	Updated the Instantaneous Short Circuit Current specification.
1.2	09/12/06	Updated the three $\pm 15\text{V}$ CMRR Typical Performance Curves.
1.3	09/26/06	Updated interstage filter capacitor values on page 1 Typical Application schematic.
1.4	05/03/07	Added the “general note” under the EC table.
1.5	10/17/07	Replaced all the PSRR curves.
1.6	01/26/10	Edited the equations on page 28 (under Tone Control).
J	04/04/13	Changed layout of National Data Sheet to TI format

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
LM4562MA/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	L4562 MA	<a href="#">Samples</a>
LM4562MAX/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	L4562 MA	<a href="#">Samples</a>
LM4562NA/NOPB	ACTIVE	PDIP	P	8	40	Green (RoHS & no Sb/Br)	CU SN	Level-1-NA-UNLIM	-40 to 85	LM 4562NA	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBsolete:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

## TAPE AND REEL INFORMATION



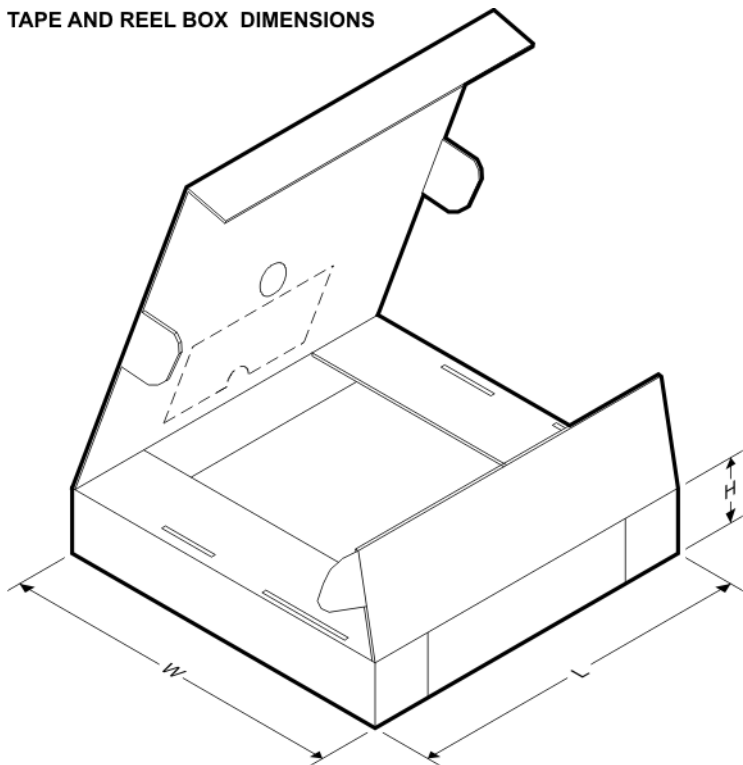
### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM4562MAX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS

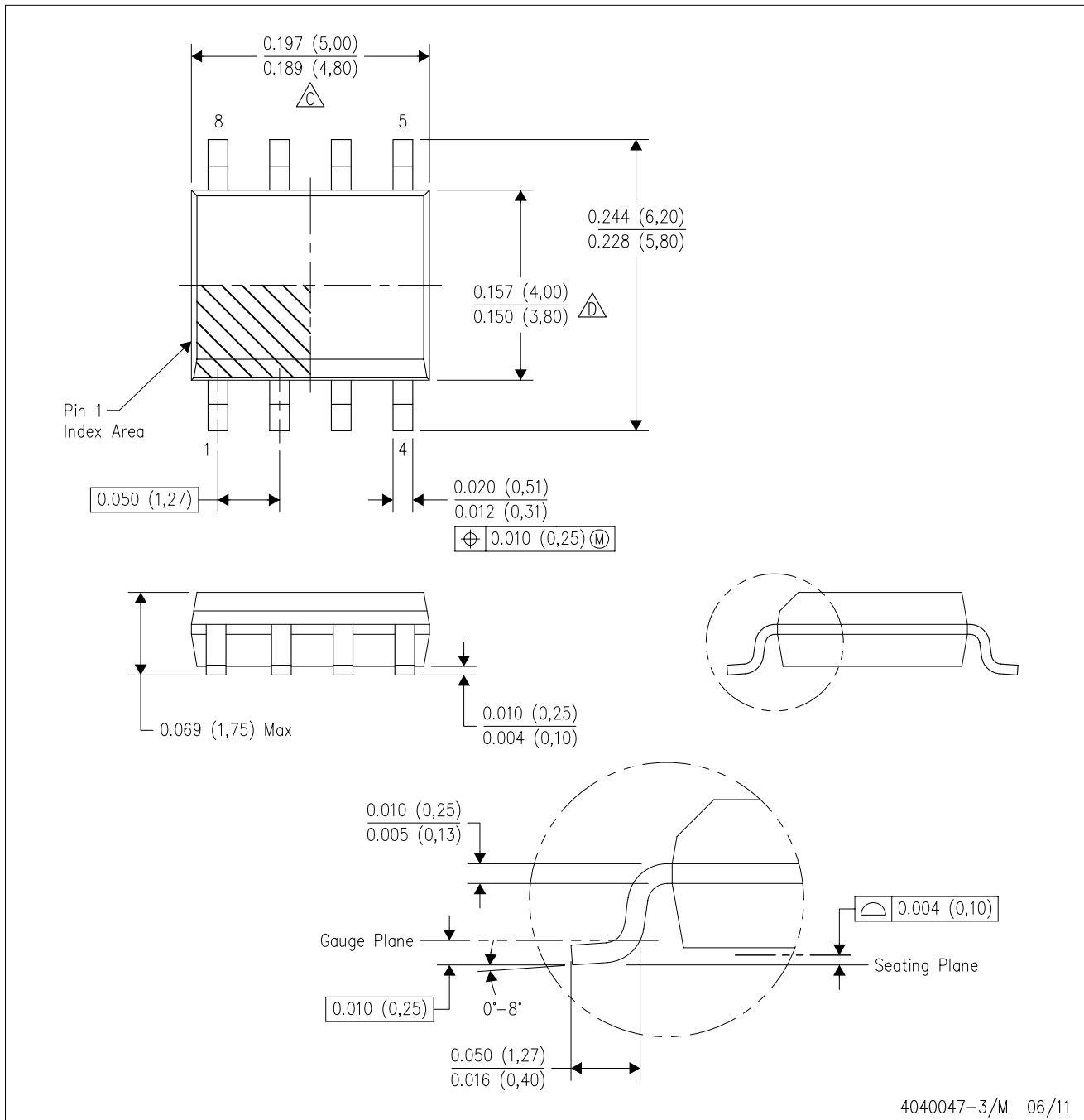


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LM4562MAX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
  - Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
  - E. Reference JEDEC MS-012 variation AA.

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. Falls within JEDEC MS-001 variation BA.

## IMPORTANT NOTICE

Texas Instruments Incorporated (TI) reserves the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete.

TI's published terms of sale for semiconductor products (<http://www.ti.com/sc/docs/stdterms.htm>) apply to the sale of packaged integrated circuit products that TI has qualified and released to market. Additional terms may apply to the use or sale of other types of TI products and services.

Reproduction of significant portions of TI information in TI data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such reproduced documentation. Information of third parties may be subject to additional restrictions. Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyers and others who are developing systems that incorporate TI products (collectively, "Designers") understand and agree that Designers remain responsible for using their independent analysis, evaluation and judgment in designing their applications and that Designers have full and exclusive responsibility to assure the safety of Designers' applications and compliance of their applications (and of all TI products used in or for Designers' applications) with all applicable regulations, laws and other applicable requirements. Designer represents that, with respect to their applications, Designer has all the necessary expertise to create and implement safeguards that (1) anticipate dangerous consequences of failures, (2) monitor failures and their consequences, and (3) lessen the likelihood of failures that might cause harm and take appropriate actions. Designer agrees that prior to using or distributing any applications that include TI products, Designer will thoroughly test such applications and the functionality of such TI products as used in such applications.

TI's provision of technical, application or other design advice, quality characterization, reliability data or other services or information, including, but not limited to, reference designs and materials relating to evaluation modules, (collectively, "TI Resources") are intended to assist designers who are developing applications that incorporate TI products; by downloading, accessing or using TI Resources in any way, Designer (individually or, if Designer is acting on behalf of a company, Designer's company) agrees to use any particular TI Resource solely for this purpose and subject to the terms of this Notice.

TI's provision of TI Resources does not expand or otherwise alter TI's applicable published warranties or warranty disclaimers for TI products, and no additional obligations or liabilities arise from TI providing such TI Resources. TI reserves the right to make corrections, enhancements, improvements and other changes to its TI Resources. TI has not conducted any testing other than that specifically described in the published documentation for a particular TI Resource.

Designer is authorized to use, copy and modify any individual TI Resource only in connection with the development of applications that include the TI product(s) identified in such TI Resource. NO OTHER LICENSE, EXPRESS OR IMPLIED, BY ESTOPPEL OR OTHERWISE TO ANY OTHER TI INTELLECTUAL PROPERTY RIGHT, AND NO LICENSE TO ANY TECHNOLOGY OR INTELLECTUAL PROPERTY RIGHT OF TI OR ANY THIRD PARTY IS GRANTED HEREIN, including but not limited to any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information regarding or referencing third-party products or services does not constitute a license to use such products or services, or a warranty or endorsement thereof. Use of TI Resources may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

TI RESOURCES ARE PROVIDED "AS IS" AND WITH ALL FAULTS. TI DISCLAIMS ALL OTHER WARRANTIES OR REPRESENTATIONS, EXPRESS OR IMPLIED, REGARDING RESOURCES OR USE THEREOF, INCLUDING BUT NOT LIMITED TO ACCURACY OR COMPLETENESS, TITLE, ANY EPIDEMIC FAILURE WARRANTY AND ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, AND NON-INFRINGEMENT OF ANY THIRD PARTY INTELLECTUAL PROPERTY RIGHTS. TI SHALL NOT BE LIABLE FOR AND SHALL NOT DEFEND OR INDEMNIFY DESIGNER AGAINST ANY CLAIM, INCLUDING BUT NOT LIMITED TO ANY INFRINGEMENT CLAIM THAT RELATES TO OR IS BASED ON ANY COMBINATION OF PRODUCTS EVEN IF DESCRIBED IN TI RESOURCES OR OTHERWISE. IN NO EVENT SHALL TI BE LIABLE FOR ANY ACTUAL, DIRECT, SPECIAL, COLLATERAL, INDIRECT, PUNITIVE, INCIDENTAL, CONSEQUENTIAL OR EXEMPLARY DAMAGES IN CONNECTION WITH OR ARISING OUT OF TI RESOURCES OR USE THEREOF, AND REGARDLESS OF WHETHER TI HAS BEEN ADVISED OF THE POSSIBILITY OF SUCH DAMAGES.

Unless TI has explicitly designated an individual product as meeting the requirements of a particular industry standard (e.g., ISO/TS 16949 and ISO 26262), TI is not responsible for any failure to meet such industry standard requirements.

Where TI specifically promotes products as facilitating functional safety or as compliant with industry functional safety standards, such products are intended to help enable customers to design and create their own applications that meet applicable functional safety standards and requirements. Using products in an application does not by itself establish any safety features in the application. Designers must ensure compliance with safety-related requirements and standards applicable to their applications. Designer may not use any TI products in life-critical medical equipment unless authorized officers of the parties have executed a special contract specifically governing such use. Life-critical medical equipment is medical equipment where failure of such equipment would cause serious bodily injury or death (e.g., life support, pacemakers, defibrillators, heart pumps, neurostimulators, and implantables). Such equipment includes, without limitation, all medical devices identified by the U.S. Food and Drug Administration as Class III devices and equivalent classifications outside the U.S.

TI may expressly designate certain products as completing a particular qualification (e.g., Q100, Military Grade, or Enhanced Product). Designers agree that it has the necessary expertise to select the product with the appropriate qualification designation for their applications and that proper product selection is at Designers' own risk. Designers are solely responsible for compliance with all legal and regulatory requirements in connection with such selection.

Designer will fully indemnify TI and its representatives against any damages, costs, losses, and/or liabilities arising out of Designer's non-compliance with the terms and provisions of this Notice.